

171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



2.95 – 6V / 2A / 0.8 – 3.6V Output

#### DESCRIPTION

The VDRM 1710x0302 series of the MagI<sup>3</sup>C Power Module family provide a fully integrated DC-DC power supply including the switching regulator with integrated MOSFETs, compensation and shielded inductor in one package. These modules require as few as 4 external components.

The 171020302 offers high efficiency and delivers up to 2A of output current. It operates with an input voltage from 2.95 to 6V and is designed for fast transient response.

It is available in a standard industrial high power density QFN package (11mm x 9mm x 2.8mm) with very good thermal performance.

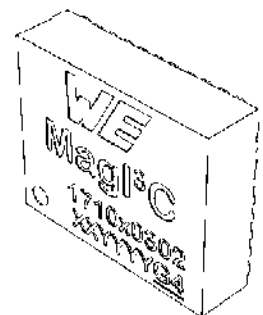
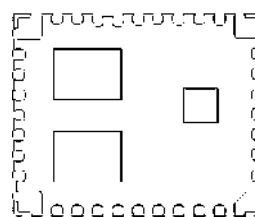
This module has an on-board protection circuitry to guard against thermal overstress and electrical damage featuring thermal shutdown, overcurrent, short circuit, overvoltage and undervoltage protections.

#### TYPICAL APPLICATIONS

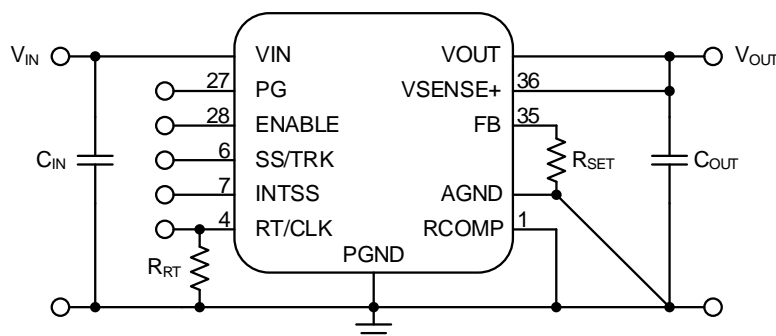
- Point-of-load DC-DC applications from 5V and 3.3V rails
- Industrial, test & measurement, medical applications
- Communication infrastructure
- System power supplies
- DSPs, FPGAs, MCUs and MPU supply
- I/O interface power supply
- High density distributed power systems

#### FEATURES

- Peak efficiency up to 95%
- Current capability up to 2A
- Input voltage range: 2.95 to 6V
- Output voltage range: 0.8 to 3.6V
- Continuous output power: 7.2W
- Integrated shielded inductor
- Low output voltage ripple: 5mV typ.
- Reference accuracy over temperature: 1% max.
- Adjustable switching frequency: 0.5 to 2 MHz
- Current Mode control
- Synchronous operation
- Forced continuous mode
- Undervoltage lockout protection (UVLO)
- Adjustable soft-start and voltage tracking
- Frequency synchronization to an external clock
- Sequencing
- Thermal shutdown
- Short circuit protection
- Cycle-by-cycle current limit
- Output overvoltage protection
- Power good indicator
- Pin compatible with 171040302 & 171060302
- Operating ambient temperature up to 85°C
- No derating within the operating temperature range
- Operating junction temp. range: -40 to 125°C
- UL94V-0 package material
- Complies with EN55022 class B radiated emissions standard



#### TYPICAL CIRCUIT DIAGRAM

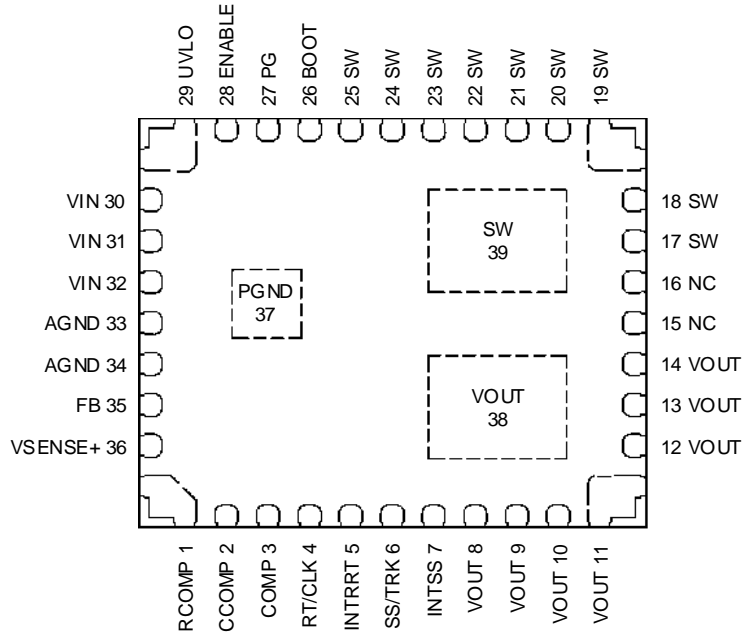


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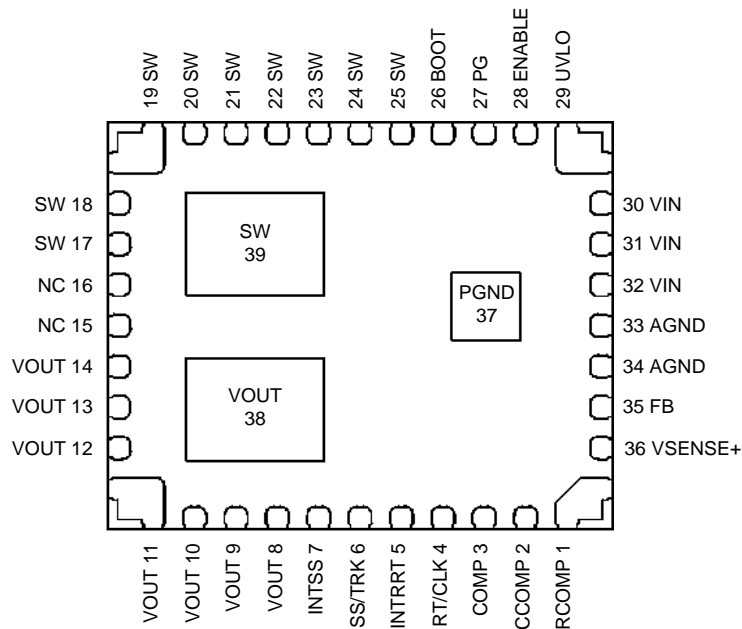
**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**PACKAGE**



Top View



Bottom View

171020302

## Magl<sup>3</sup>C Power Module

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#### PIN DESCRIPTION

SYMBOL	NUMBER	TYPE	DESCRIPTION
VIN	30,31,32	Power	Input Voltage. Place input capacitors as close as possible
VOUT	8,9,10,11, 12,13,14, 38	Power	Output voltage. Place output capacitors as close as possible. For thermal performance use copper plane(s) at these pins.
AGND	33,34	Supply	Analog ground for internal circuitry. Connect to power ground
PGND	37	Power	Power ground for the internal switching circuitry. Connect to copper plane(s) with thermal vias for thermal performance.
VSENSE+	36	Input	Connect to positive terminal of the output capacitor. An internal resistor of 1430 Ω is connected internally between V <sub>SENSE+</sub> and FB. This is the top resistor of the feedback voltage divider.
FB	35	Input	A resistor (R <sub>SET</sub> ) from FB to sets the output voltage. This is the bottom resistor of the feedback voltage divider.
RT/CLK	4	Input	An external resistor from RT/CLK to AGND adjusts the switching frequency of the device. This pin can also be used to synchronize the switching frequency of the module to an external clock.
INTRRT	5	Analog	Internal resistor which sets the default switching frequency.
RCOMP	1	Analog	Internal resistor of the compensation network. Must be connected to AGND.

#### OPTIONAL

SYMBOL	NUMBER	TYPE	DESCRIPTION
UVLO	29	Input	An internal undervoltage lock out resistor of 34kΩ is connected to the enable pin. If pin 29 is connected to analog ground, the internal UVLO resistor divider will be activated. For input voltages below 3.3V this pin should be left open and an optional resistor from enable to analog ground sets the UVLO to values between 2.95 and 3.3 V.
ENABLE	28	Input	Enable pin. Internally pull-up current source. Pull to analog ground to disable the module . Can be left floating to enable the module.
PG	27	Output	Open drain output. The PG pin pulls low during thermal shutdown, over-current, output overvoltage or undervoltage or disabled device. A pull-up resistor is required.
SS/TRK	6	Input	Internal current source to charge the soft start capacitor. Connect an external capacitor to optionally increase the soft-start time. A voltage applied to this pin allows tracking and sequencing.
INTSS	7	Analog	An internal 3.3nF capacitor is connected to this pin. If pin 7 is connected to analog ground, a 1.1ms soft start time is selected.

#### AUXILIARY

SYMBOL	NUMBER	TYPE	DESCRIPTION
COMP	3	Output	Output of the error amplifier. Do not connect this pin
CCOMP	2	Analog	Internal capacitor of the compensation network. Do not connect this pin.
BOOT	26	Supply	Internal bootstrap pin for the high side MOSFET.
SWITCH	17,18,19, 20,21,22, 23,24,25, 39	Power	Internal switch node. Do not connect these pins.
NC	15,16		Not connected to internal circuitry.

**171020302**

**MagI<sup>3</sup>C** Power Module  
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**ORDERING INFORMATION**

ORDER CODE	SPECIFICATIONS	PACKAGE	PACKAGING UNIT
171020302	2A / 7.2W version	BQFN-39	Tape and Reel, 250 pieces
178020302	2A / 7.2W version	Eval Board	1

**PIN COMPATIBLE FAMILY MEMBERS**

ORDER CODE	SPECIFICATIONS	PACKAGE	PACKAGING UNIT
171040302	4A / 14.4W version	BQFN-39	Tape and Reel, 250 pieces
178040302	4A / 14.4W version	Eval Board	1
171060302	6A / 21.6W version	BQFN-39	Tape and Reel, 250 pieces
178060302	6A / 21.6W version	Eval Board	1

**PACKAGE SPECIFICATIONS**

Weight	Molding compound	UL class	Certificate number
0.54g	EME-G770H	UL94 V-0	E41429

**SALES INFORMATION**

SALES CONTACT
<p>Würth Elektronik eiSos GmbH &amp; Co. KG            EMC &amp; Inductive Solutions            Max-Eyth-Str. 1            74638 Waldenburg            Germany            Tel. +49 (0) 7942 945 0  <a href="http://www.we-online.com/powermodules">www.we-online.com/powermodules</a>            Technical support: <a href="mailto:powermodules@we-online.com">powermodules@we-online.com</a></p>

171020302

**MagI<sup>3</sup>C** Power Module  
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### ABSOLUTE MAXIMUM RATINGS

Caution:

Exceeding the listed absolute maximum ratings may affect the device negatively and may cause permanent damage.

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN <sup>(1)</sup>	MAX <sup>(1)</sup>	
VIN	Input pin voltage	-0.3	7	V
VOUT	Output pin voltage	-0.6	V <sub>IN</sub>	V
FB	Feedback pin voltage	-0.3	3	V
UVLO	Undervoltage lockout pin voltage	-0.3	3.3	V
EN	Enable pin Voltage	-0.3	7	V
	Enable pin source current	-	100	μA
RT/CLK	RT/CLK pin voltage	-0.3	6	V
	RT/CLK pin current	-	±100	μA
SS/TRK	SS/TRK pin voltage	-0.3	3	V
	SS/TRK pin current	-	±100	μA
PG	Power Good pin voltage	-0.3	7	V
	Power Good pin current	-	10	mA
COMP	COMP pin voltage	-0.3	3	V
	COMP pin current	-	100	μA
INTSS	INTSS pin voltage	-0.3	3	V
INTRRT	INTRRT pin voltage	-0.3	6	V
RCOMP	RCOMP pin voltage	-0.3	3	V
CCOMP	CCOMP pin voltage	-0.3	3	V
VSENSE+	VSENSE+ pin voltage	-0.3	V <sub>out</sub>	V
SW	SW pin voltage	-0.6	7	V
	10ns transient	-2	7	V
BOOT	BOOT pin voltage	-	V <sub>SW</sub> +8V	V
T <sub>storage</sub>	Assembled, non operating storage temperature	-65	150	°C
T <sub>SOLR</sub>	Peak case/leads temperature during reflow soldering, max. 30sec. (JEDEC J-STD020) Maximum three cycles!	-	245±5	°C
Mechanical shock: Mil-STD-883D, Method 2002.2, 1ms, ½ sine, mounted		-	1500	G
Mechanical vibration: Mil-STD-883D, Method 2007.2, 20-2000Hz		-	20	G

171020302

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#### OPERATING CONDITIONS

Operating conditions are conditions under which operation of the device is intended to be functional. All values are referenced to GND.

MIN and MAX limits are valid for the recommended ambient temperature range of **-40°C to 85°C**. Typical values represents statistically the utmost probability at following conditions:  $V_{IN} = 3.3V$ ,  $V_{OUT} = 1.8V$ ,  $I_{OUT} = 2A$ ,  $C_{IN1} = 47\mu F$  ceramic,  $C_{IN2} = 220\mu F$  polymer electrolytic,  $C_{OUT1} = 47\mu F$  ceramic,  $C_{OUT2} = 100\mu F$  poly-tantalum unless otherwise noted.

SYMBOL	PARAMETER	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
$V_{IN}$	Input voltage	2.95	-	6	V
$V_{OUT}$	Output voltage (depending on input voltage and switching frequency)	0.8	-	3.6	V
$T_A$	Ambient temperature range	-40	-	85 <sup>(3)</sup>	°C
$T_{JOP}$	Junction temperature range	-40	-	125	°C
$I_{OUT}$	Nominal output current			2	A

#### THERMAL SPECIFICATIONS

SYMBOL	PARAMETER	TYP <sup>(2)</sup>	UNIT
$\Theta_{JA}$	Junction-to-ambient thermal resistance <sup>(4)</sup>	12	°C/W
$\Psi_{JT}$	Junction-to-top <sup>(5)</sup>	2.2	°C/W
$\Psi_{JB}$	Junction-to-board <sup>(6)</sup>	9.7	°C/W
$T_{SD}$	Thermal shutdown, rising	175	°C
	Thermal shutdown hysteresis, falling	15	°C

171020302

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MIN and MAX limits are valid for the recommended ambient temperature range of **-40°C to 85°C**. Typical values represents statistically the utmost probability at following conditions:  $V_{IN} = 3.3V$ ,  $V_{OUT} = 1.8V$ ,  $I_{OUT} = 2A$ ,  $C_{IN1} = 47\mu F$  ceramic,  $C_{IN2} = 220\mu F$  polymer electrolytic,  $C_{OUT1} = 47\mu F$  ceramic,  $C_{OUT2} = 100\mu F$  poly-tantalum unless otherwise noted.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
<b>Output current</b>						
$I_{OCP}$	Over current protection		-	3.5	-	A
<b>Accuracy</b>						
$V_{FB}$	Reference accuracy	$T_A = 25^\circ C$ , $I_{OUT} = 0A$ with internal feedback resistor	-	-	$\pm 1^{(7)}$	%
	Temperature variation	$-40^\circ C \leq T_A \leq 85^\circ C$ , $I_{OUT} = 0A$	-	$\pm 0.3$	-	%
$V_{OUT}$	Line regulation	Over $V_{IN}$ range, $T_A = 25^\circ C$ , $I_{OUT} = 0A$	-	$\pm 0.1$	-	%
	Load regulation	Over $I_{OUT}$ range, $T_A = 25^\circ C$	-	$\pm 0.1$	-	%
	Total output voltage variation		-	-	$\pm 1.5$	%
	Output voltage ripple	10 $\mu F$ ceramic, 20MHz BW <sup>(8)</sup>	-	5	-	mV <sub>pp</sub>
<b>Switching frequency</b>						
$f_{SW}$	Switching frequency	Using RT mode	500	-	2000	kHz
		RT/CLK pin open	400	500	600	kHz
$f_{CLK}$	Synchronization clock frequency range	Using CLK mode	500	-	2000	kHz
	Minimum CLK pulse width		75	-	-	ns
$V_{CLK-H}$	RT/CLK high threshold	Relative to AGND	2.2	-	3.3	V
$V_{CLK-L}$	RT/CLK low threshold		-0.3	-	0.4	V
$f_{CLK}$	RT/CLK to switch node delay		-	90	-	ns
	PLL lock-in-time		-	14	-	$\mu s$
<b>Enable and undervoltage lockout</b>						
$V_{UVLO}$	$V_{IN}$ undervoltage threshold	$V_{IN}$ increasing, UVLO pin connected to AGND	-	3.05	3.135	V
		$V_{IN}$ decreasing, UVLO pin connected to AGND	2.5	2.75	-	V
$V_{ENABLE}$	Enable threshold trip point	Enable logic high voltage	-	1.25	-	V
		Enable logic low voltage	-0.3	-	1.0	V
<b>Power Good</b>						
PG	Power Good threshold	$V_{OUT}$ rising, $V_{OUT}$ GOOD	-	93	-	%
		$V_{OUT}$ rising, $V_{OUT}$ FAULT	-	107	-	%
		$V_{OUT}$ falling, $V_{OUT}$ GOOD	-	105	-	%
		$V_{OUT}$ falling, $V_{OUT}$ FAULT	-	91	-	%
	Power Good low voltage	$I_{PG} = 0.33mA$	-	-	0.3	V

171020302

**MagI<sup>3</sup>C** Power Module  
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## ELECTRICAL SPECIFICATIONS

SYMBOL	PARAMETER	TEST CONDITIONS	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT	
<b>Efficiency</b>							
$\eta$	Efficiency	$V_{IN} = 5V$ $I_{OUT} = 1A$	$V_{OUT} = 3.3V, f_{SW} = 1.5MHz$	-	95	-	%
			$V_{OUT} = 2.5V, f_{SW} = 1.5MHz$	-	93	-	%
			$V_{OUT} = 1.8V, f_{SW} = 1.0MHz$	-	92	-	%
			$V_{OUT} = 1.5V, f_{SW} = 1.0MHz$	-	91	-	%
			$V_{OUT} = 1.2V, f_{SW} = 750kHz$	-	90	-	%
			$V_{OUT} = 1.0V, f_{SW} = 650kHz$	-	88	-	%
		$V_{IN} = 3.3V$ $I_{OUT} = 1A$	$V_{OUT} = 1.8V, f_{SW} = 1.0MHz$	-	93	-	%
			$V_{OUT} = 1.5V, f_{SW} = 1.0MHz$	-	92	-	%
			$V_{OUT} = 1.2V, f_{SW} = 750kHz$	-	91	-	%
			$V_{OUT} = 1.0V, f_{SW} = 650kHz$	-	89	-	%
			$V_{OUT} = 0.8V, f_{SW} = 650kHz$	-	87	-	%
			<b>Input and output capacitors</b>				
$C_{IN}$	External input capacitor	Ceramic, required	47 <sup>(9)</sup>	-	-	$\mu F$	
		Non ceramic, recommended in addition to ceramic	-	220 <sup>(9)</sup>	-	$\mu F$	
$C_{OUT}$	External output capacitor	Ceramic, optionally in addition to ceramic	47 <sup>(10)</sup>	150	650 <sup>(11)</sup>	$\mu F$	
		Non ceramic	-	100 <sup>(10)</sup>	1000 <sup>(11)</sup>	$\mu F$	
	Output capacitor ESR	-	-	25	$m\Omega$		
<b>Transient Response</b>							
$t_{TR}$	Transient Response	Recovery time 1A/ $\mu s$ load step from 0.5A to 1.5A	-	80	-	$\mu s$	
		$V_{OUT}$ over/undershoot 1A/ $\mu s$ load step from 0.5A to 1.5A	-	45	-	mV	
<b>Input quiescent current</b>							
$I_{SD}$	Shutdown quiescent current	$V_{ENABLE} = 0V$	-	70	100	$\mu A$	

## RELIABILITY

SYMBOL	PARAMETER	TEST CONDITIONS	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
MTBF	Mean Time Between Failures	Confidence level 60%, $T_A=55^\circ C$ , Activation energy 0.7eV, 1000 hrs test duration, 128756 samples, 0 fail		1·10 <sup>10</sup>		h



171020302

## MagI<sup>3</sup>C Power Module

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#### NOTES

- (1) Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlation using Statistical Quality Control (SQC) methods.
- (2) Typical numbers are valid at 25°C ambient temperature and represent statistically the utmost probability assuming the Gaussian distribution.
- (3) Depending on heat sink design, number of PCB layers, copper thickness and air flow.
- (4) Measured on a 100 x 100mm two layer board, with 35µm (1 ounce) copper, no air flow
- (5) The junction-to-top characterization parameter,  $\Psi_{JT}$ , estimates the junction temperature,  $T_J$ , of a device in a real system, using a procedure described in JESD51-2A (sections 6 and 7).  $T_J = \Psi_{JT} * P_{dis} + T_T$ ; where  $P_{dis}$  is the power dissipated in the device and  $T_T$  is the temperature of the top of the device.
- (6) The junction-to-board characterization parameter,  $\Psi_{JB}$ , estimates the junction temperature,  $T_J$ , of a device in a real system, using a procedure described in JESD51-2A (sections 6 and 7).  $T_J = \Psi_{JB} * P_{dis} + T_B$ ; where  $P_{dis}$  is the power dissipated in the device and  $T_B$  is the temperature of the board 1mm from the device.
- (7) The stated limit of the set-point voltage tolerance includes the tolerance of both the internal voltage reference and the internal adjustment resistor. The overall output voltage tolerance is affected by the tolerance of the external  $R_{SET}$  resistor.
- (8) The industry standard for comparison of the output voltage ripple between switching regulators or modules requires a 10µF ceramic (sometimes additional 1µF ceramic in parallel) at the point of load where the voltage measurement is done using an oscilloscope with its probe and probe jack for low voltage/high frequency (low impedance) measurement. The oscilloscopes bandwidth is limited at 20MHz.
- (9) A minimum of 47µF of ceramic capacitance is required across the input for proper operation. Locate the capacitor directly at  $V_{IN}$  of the device. An additional 220µF of bulk capacitance is recommended.
- (10) The amount of required output capacitance varies depending on the output voltage. The amount of required capacitance must include at least 47µF of ceramic capacitance. Locate the capacitance close to the device. Adding additional capacitance close to the load improves the response of the regulator to load transients.
- (11) When using both ceramic and non-ceramic output capacitance, the combined maximum must not exceed 1200µF.

# 171020302

## Mag<sup>3</sup>C Power Module VDRM – Variable Step Down Regulator Module

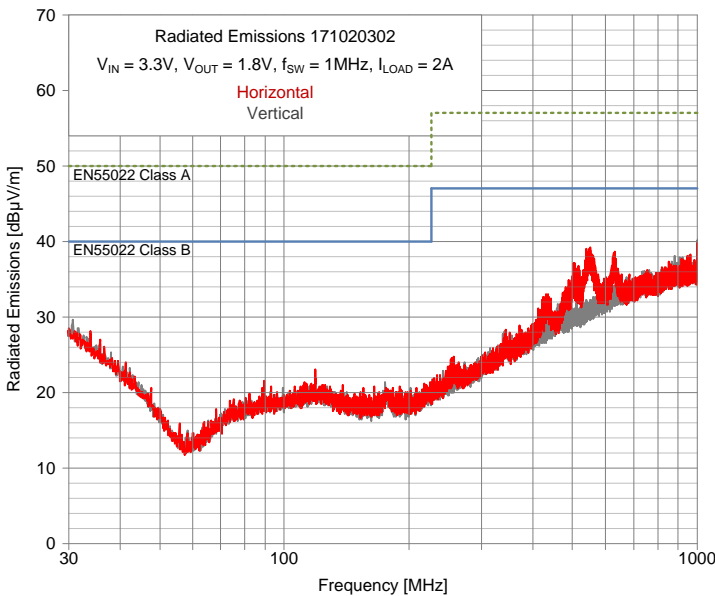
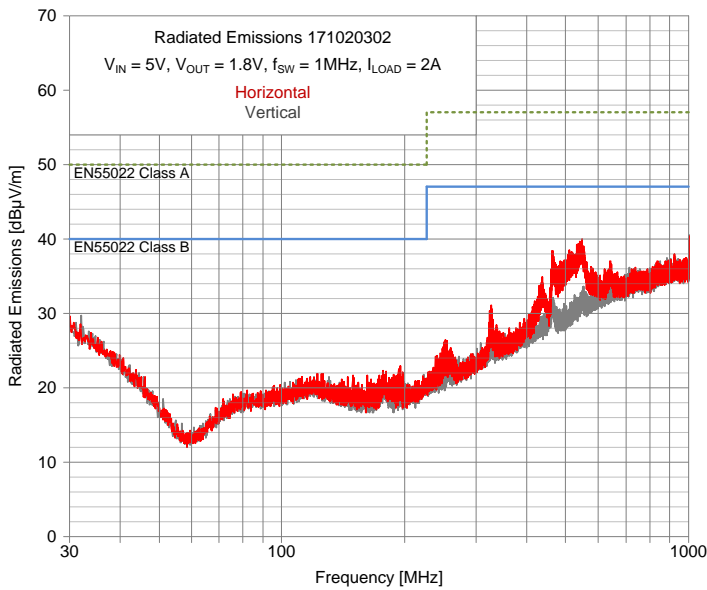


### TYPICAL PERFORMANCE CURVES

If not otherwise specified, the following conditions apply:  $V_{IN} = 3.3V - 5V$ ;  $C_{IN} = 2 \times 47\mu F$  X7R ceramic;  $C_{OUT} = 2 \times 47\mu F$  X7R ceramic,  $T_{AMB} = 25^{\circ}C$ .

### RADIATED EMISSIONS EN55022 (CISPR-22) CLASS B COMPLIANT

Measured on module with PCB and without external filters at 3m antenna distance

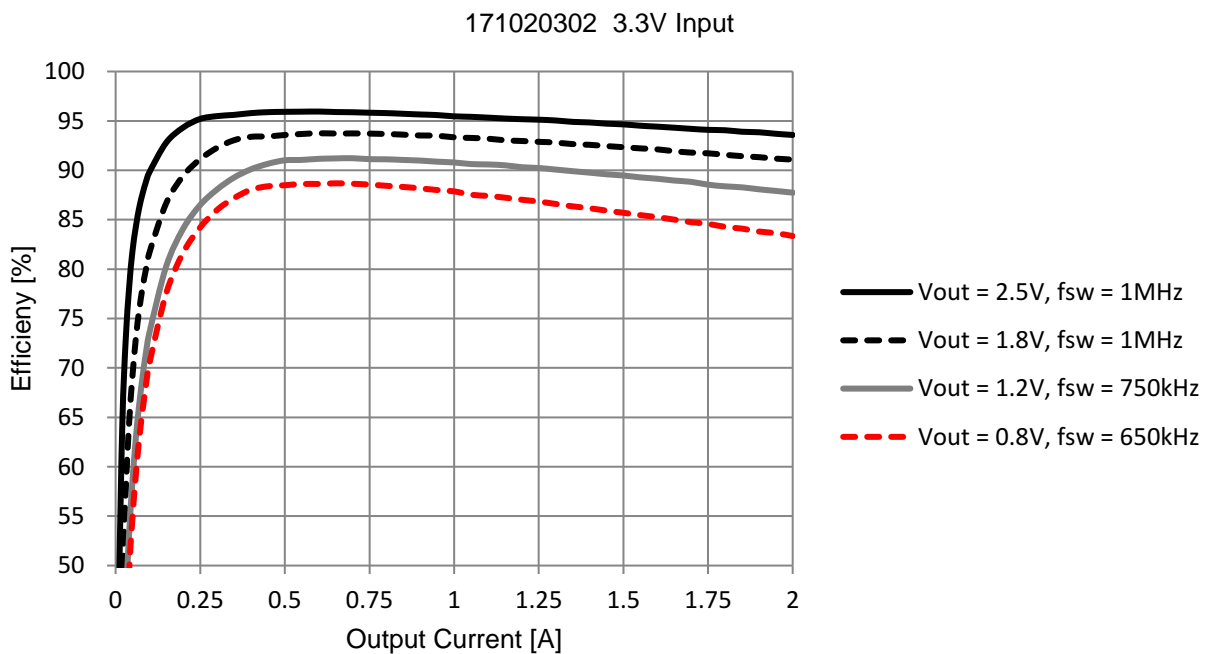
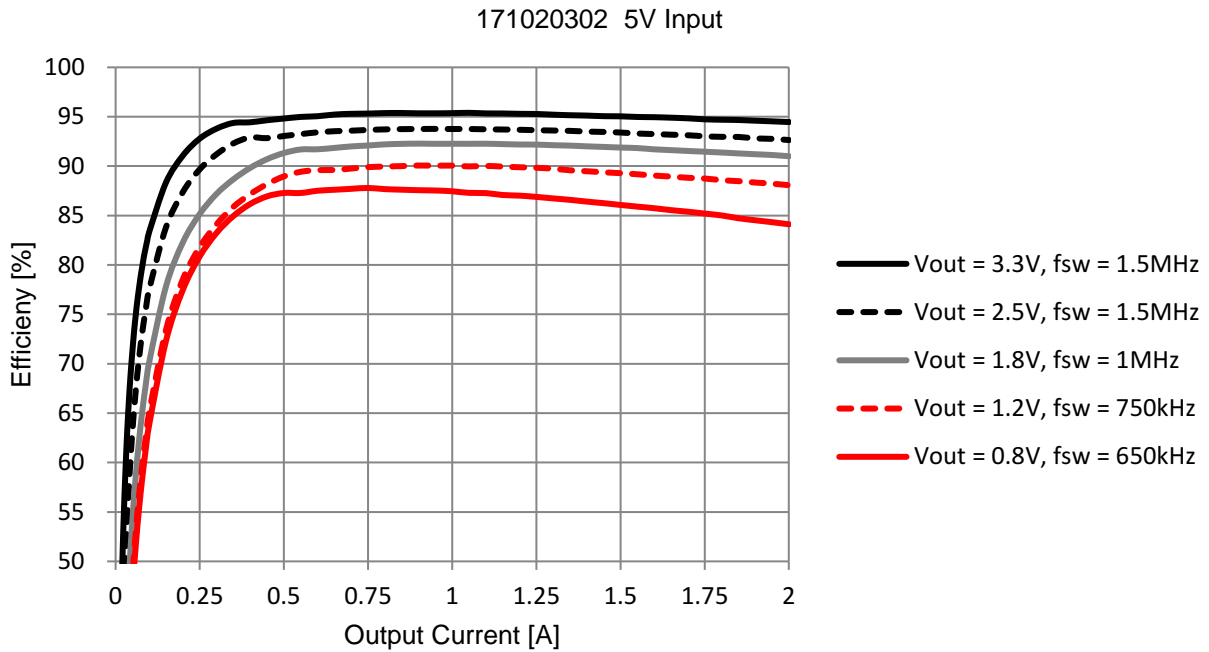


# 171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



## EFFICIENCY

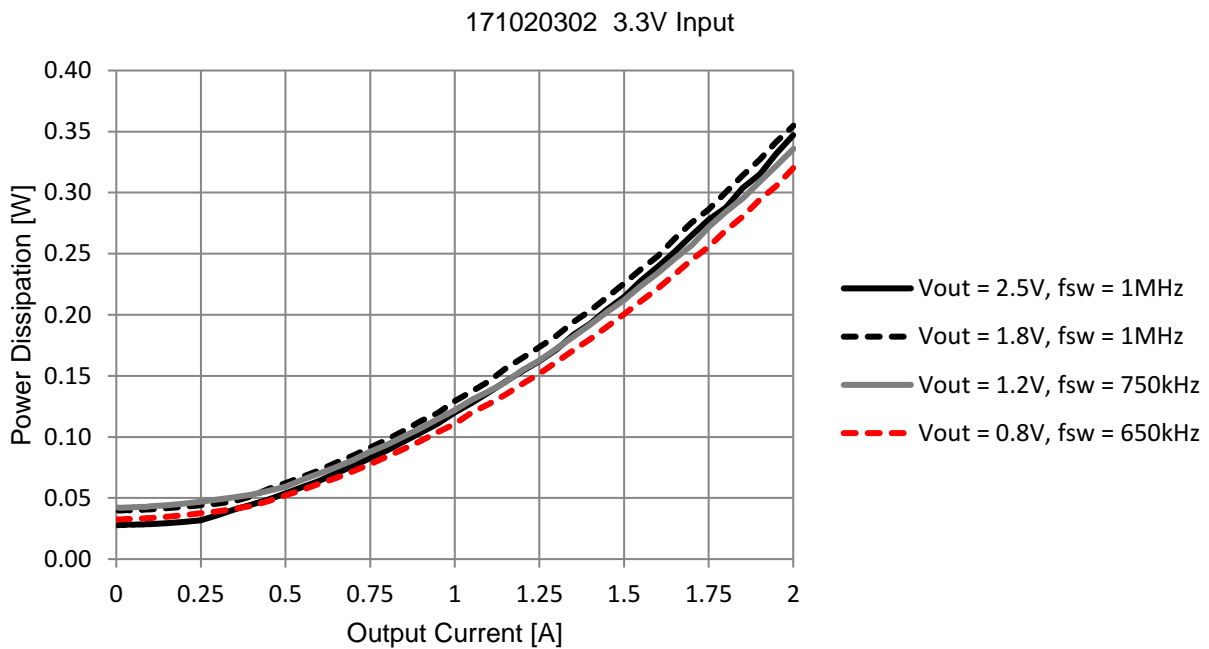
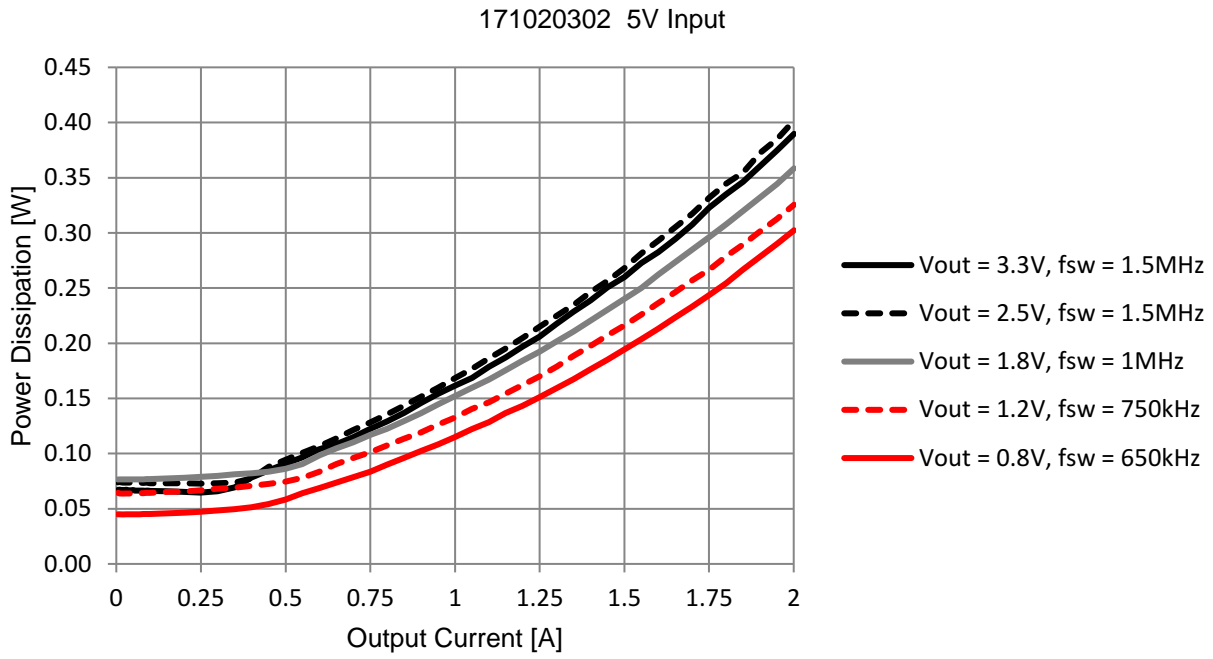


# 171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



## POWER DISSIPATION

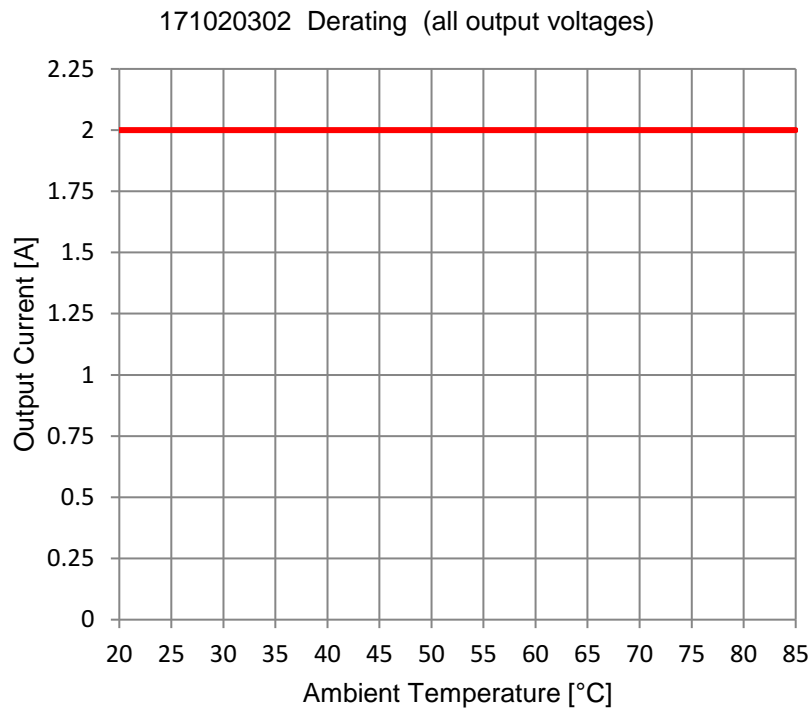


# 171020302

**MagI<sup>3</sup>C** Power Module  
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## OUTPUT POWER DERATING



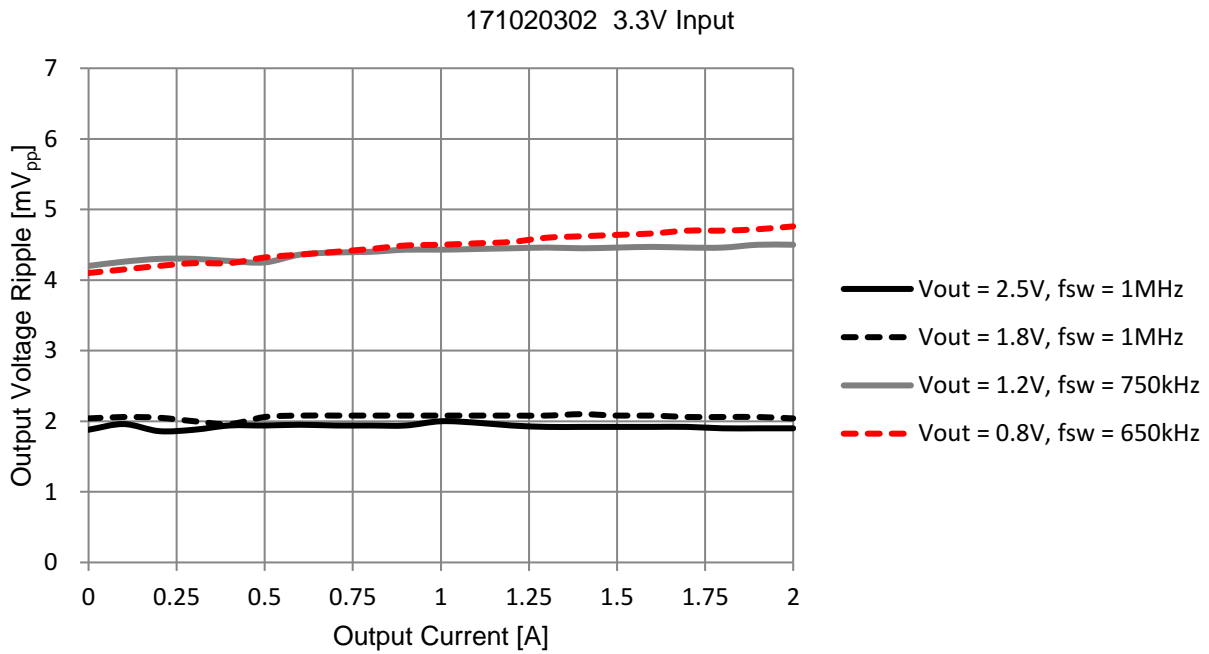
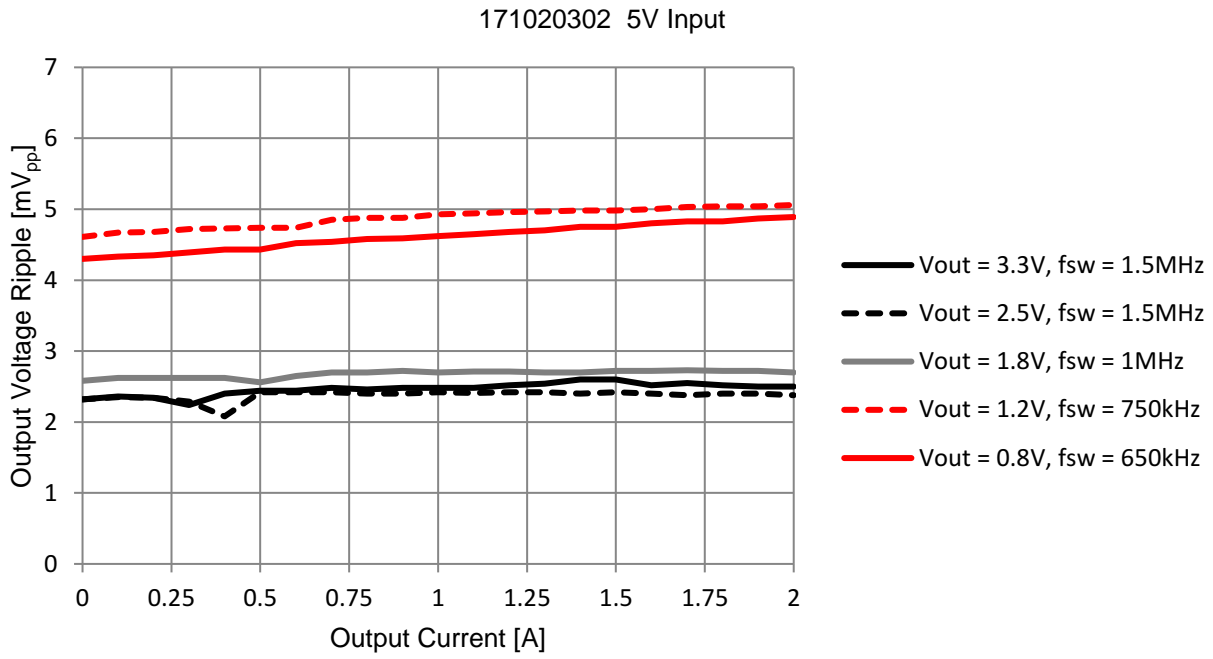
Note : see  $T_A$  limits in operating conditions on page 6.

# 171020302

**MagI<sup>3</sup>C** Power Module  
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## OUTPUT VOLTAGE RIPPLE



171020302

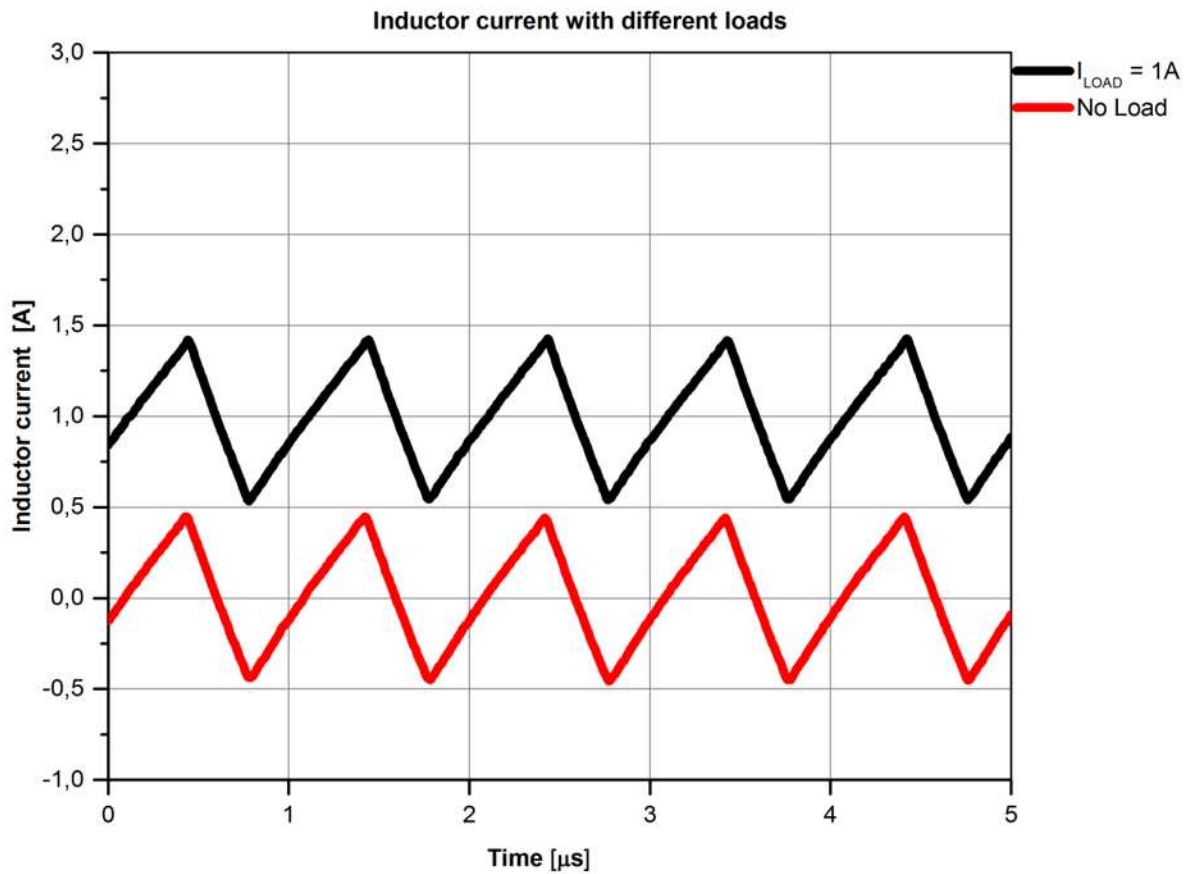
**MagI<sup>3</sup>C** Power Module  
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## LIGHT LOAD OPERATION

The 171020302 forces the CCM (Continuous Conduction Mode) operation at light load (forced CCM). The inductor current during  $t_{OFF}$  can flow in the opposite direction, i.e. from the output capacitor and load to ground, through the low side MOSFET. In this way during  $t_{OFF}$  the output capacitor is discharged and loses the excess of charge gathered during  $t_{ON}$ .

In this way the switching frequency always remains constant, giving a relevant advantage in terms of filtering and avoiding interferences in undesired frequency ranges. Any load change will simply shift the inductor current up and down (see figure below).



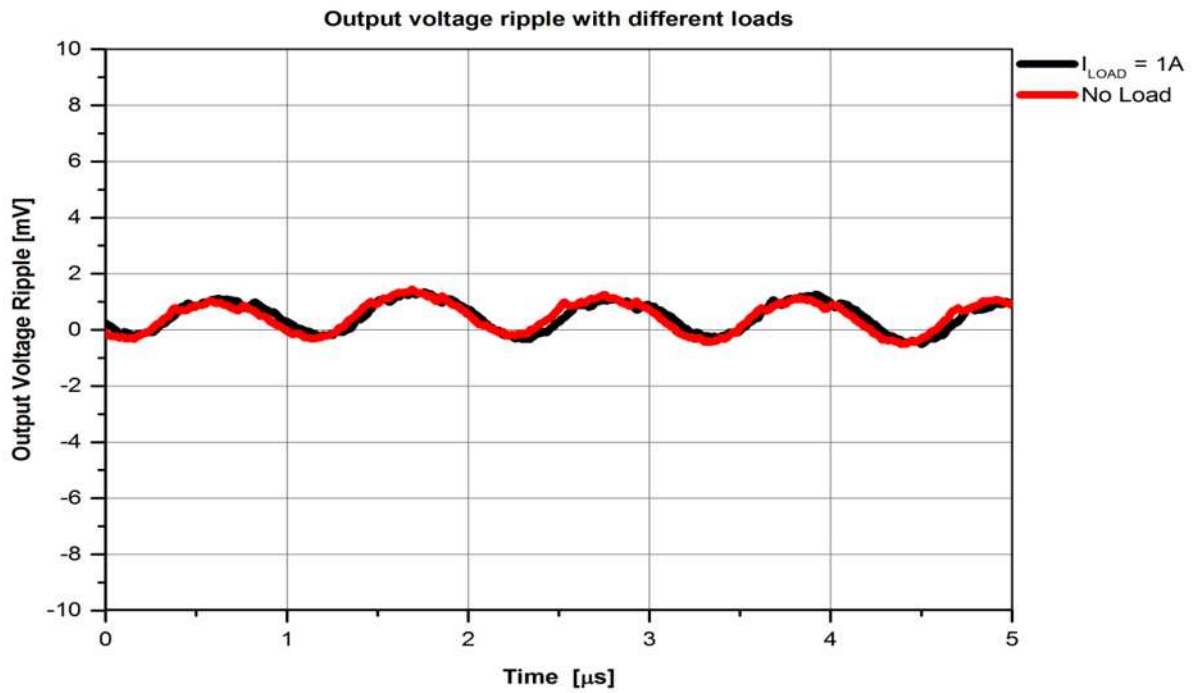
171020302

**MagI<sup>3</sup>C** Power Module  
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### OUTPUT VOLTAGE RIPPLE AT LIGHT LOAD

In addition, the forced CCM implemented in the 171020302 keeps the output voltage ripple constant and low at all conditions (see figure below).





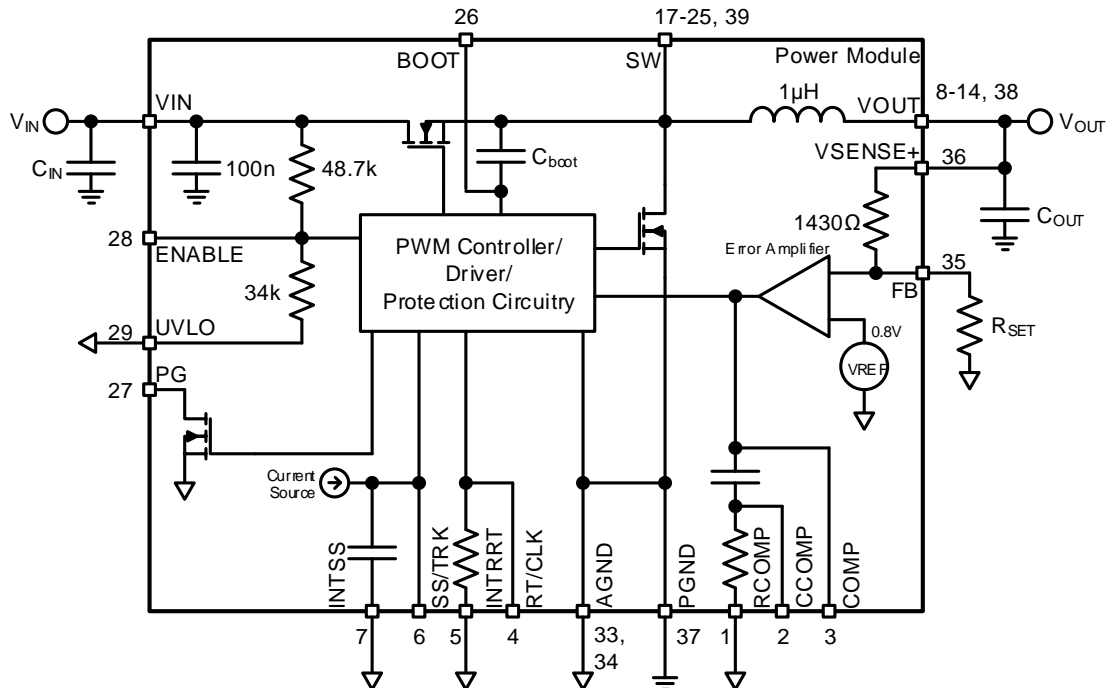
171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### BLOCK DIAGRAM



#### CIRCUIT DESCRIPTION

The MagI<sup>3</sup>C Power Module series 1710x0302 is based on a synchronous step down regulator with integrated MOSFETs and a power inductor. The control scheme is based on a Current Mode (CM) regulation loop.

The V<sub>OUT</sub> of the regulator is divided with the feedback resistor network of internal 1430Ω and external R<sub>SET</sub> and fed into the FB pin. The error amplifier compares this signal with the internal 0.803V reference. The error signal is amplified and controls the on-time of a fixed frequency pulse width generator. This signal drives the power MOSFETs.

The Current Mode architecture features a constant frequency during load steps. Only the on-time is modulated. It is internally compensated and stable with low ESR output capacitors and requires no external compensation network.

This architecture supports fast transient response and very small output ripple values (less than 10mV) are achieved.

171020302

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#### DESIGN FLOW

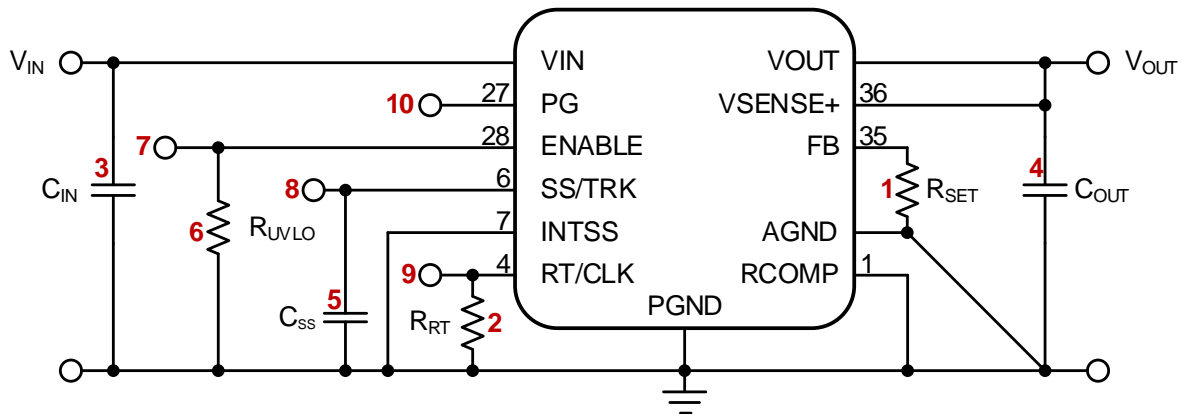
The next 10 simple steps will show how to select the external components to design your power application.

#### Essential Steps

1. Set output voltage
2. Set operating frequency
3. Select input capacitor
4. Select output capacitor

#### Optional Steps

5. Select soft-start capacitor
6. Select undervoltage lockout divider
7. Enable / Disable
8. Voltage tracking
9. Synchronization to an external clock
10. Power Good



# 171020302

## MagI<sup>3</sup>C Power Module VDRM – Variable Step Down Regulator Module



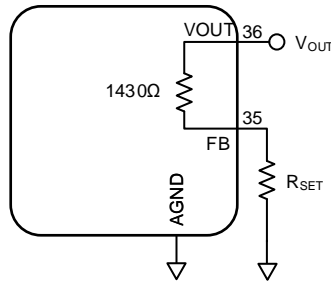
### Step 1 Setting the output voltage (V<sub>OUT</sub>)

The output voltage is selected with a resistor divider across FB pin and AGND. The top resistor of 1430 Ω of the feedback voltage resistor divider is located inside the module. The output voltage adjustment range is from 0.8V to 3.6V.

$$R_{SET} = \frac{V_{REF} \cdot 1430\Omega}{V_{OUT} - V_{REF}} \quad (\Omega) \quad (1)$$

V<sub>REF</sub> is the internal reference voltage (0.8V).

V <sub>OUT</sub>	3.3V	3.0V	2.5V	1.8V	1.5V	1.2V	1.0V	0.8V
R <sub>SET</sub> (E96)	453Ω	523Ω	665Ω	1130Ω	1620Ω	2870Ω	5620Ω	open



171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### Step 2 Setting the operating frequency ( $f_{sw}$ )

The switching frequency must be selected according to the input voltage, output voltage and load current for the best performance in loop regulation and transient response.

Note:  $R_{RT}$  open ( $f_{sw} = 500$  kHz) is only allowed under specific conditions (see table below)

OPERATING FREQUENCY [kHz]	$R_{RT}$ [k $\Omega$ ]	$V_{IN} = 5V$				$V_{IN} = 3.3V$	
		$I_{OUT} = 0$ to 1.5A		$I_{OUT} > 1.5A$		$I_{OUT} = 0$ to 2A	
		$V_{OUT}$ RANGE [V]		$V_{OUT}$ RANGE [V]		$V_{OUT}$ RANGE [V]	
		MIN	MAX	MIN	MAX	MIN	MAX
500	open	0.8	1.4	0.8	0.8	0.8	1.1
550	3400	0.8	1.6	0.8	0.9	0.8	1.2
600	1800	0.8	1.9	0.8	1.1	0.8	2.0
650	1200	0.8	2.4	0.8	1.2	0.8	2.2
700	887	0.8	3.6	0.8	1.3	0.8	2.4
750	715	0.9	3.6	0.9	1.5	0.8	2.5
800	590	0.9	3.6	0.9	1.7	0.8	2.5
900	511	1.0	3.6	1.0	2.2	0.8	2.5
1000	348	1.2	3.6	1.2	2.5	0.8	2.5
1250	232	1.4	3.6	1.4	3.3	1.0	2.5
1500	174	1.7	3.6	1.7	3.6	1.1	2.5
1750	137	2.0	3.6	2.0	3.6	1.3	2.4
2000	113	2.3	3.6	2.3	3.6	1.5	2.3

171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### Step 3 Select input capacitor (C<sub>IN</sub>)

The energy at the input of the power module is stored in the input capacitor. A small input capacitor (100nF) is integrated inside the 1710x0302 MagI<sup>3</sup>C Power Module series, ensuring good EMI performance. Additional external input capacitance is required to the power module to provide cycle-by-cycle switch current and to support load transients. The external input capacitors must be placed directly at the VIN pin. Input capacitor selection is generally directed to satisfy the input ripple current requirements rather than by capacitance value. Input ripple current rating is dictated by the equation:

$$I_{C_{IN}RMS} \approx I_{OUT} \cdot \sqrt{D \cdot (1 - D)} \quad (2) \quad \text{where } D \approx \frac{V_{OUT}}{V_{IN}}$$

As a point of reference, the worst case ripple current will occur when the module is presented with full load current and when  $V_{IN} = 2 \times V_{OUT}$ .

Recommended minimum input capacitance is 47µF X7R or X5R ceramic with a voltage rating at least 25% higher than the maximum applied input voltage for the application. It is also recommended that attention be paid to the voltage and temperature deratings of the capacitor selected. It should be noted that ripple current rating of ceramic capacitors may be missing from the capacitor data sheet and you may have to contact the capacitor manufacturer for this rating.

If the system design requires a certain minimum value of peak-to-peak input ripple voltage ( $\Delta V_{IN}$ ) then the following equation may be used:

$$C_{IN} \geq \frac{I_{OUT} \cdot D \cdot (1 - D)}{f_{SWCCM} \cdot \Delta V_{IN}} \quad (3) \quad \text{where } D \approx \frac{V_{OUT}}{V_{IN}} \quad \text{CCM} = \text{continuous conduction mode}$$

Additional bulk capacitance with higher ESR may be required to damp any resonant effects of the input capacitance and parasitic inductance of the incoming supply lines or the existing inductance of the input circuit.

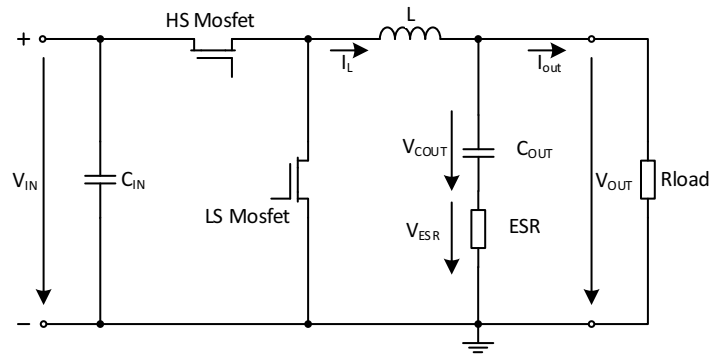
171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### Step 4 Select output capacitor (C<sub>OUT</sub>)



None of the required output capacitors are integrated within the module. The output capacitor must meet the worst case RMS current rating of  $0.5 \cdot \Delta I_L$ , as calculated in equation (4).

$$\Delta I_L = \frac{V_{OUT} \cdot (V_{IN} - V_{OUT})}{f_{SW} \cdot L \cdot V_{IN}} \quad (4)$$

#### Selection by output voltage ripple requirements

The capacitor should be selected in order to minimize the output voltage ripple and provide a stable voltage at the output. Under steady state conditions, the voltage ripple observed at the output can be defined as:

$$V_{OUT \text{ ripple}} = \Delta I_L \cdot ESR + \Delta I_L \cdot \frac{1}{8 \cdot f_{SW} \cdot C_{OUT}} \quad (5)$$

Very low ESR capacitors, like ceramic and polymer electrolytic, are recommended. If a low ESR capacitor is selected, equation (4) can be simplified and a first condition for the minimum capacitance value can be derived:

$$C_{OUT} \geq \frac{\Delta I_L}{8 \cdot V_{OUT \text{ ripple}} \cdot f_{SW}} \quad (6)$$

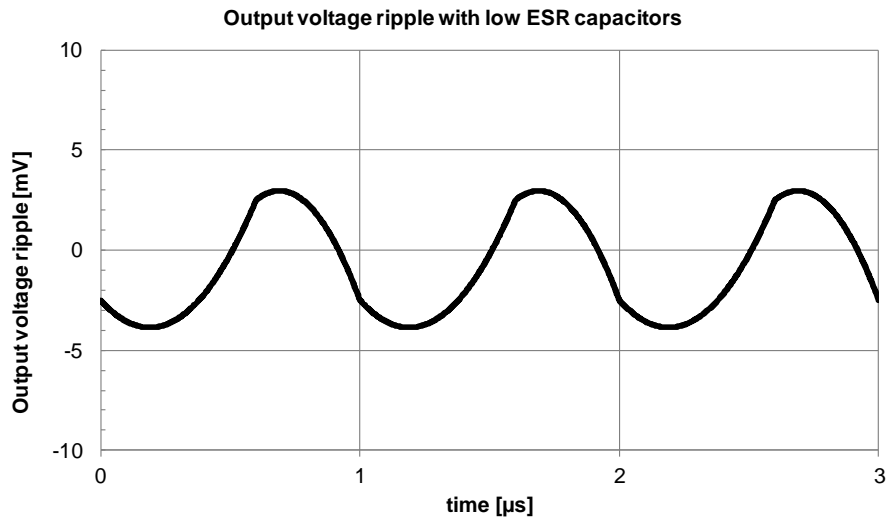
Beyond that, additional capacitance will reduce output ripple as long as the ESR is low enough to permit it. Please consider the derating of the nominal capacitance value due to temperature, aging and applied DC voltage.

171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



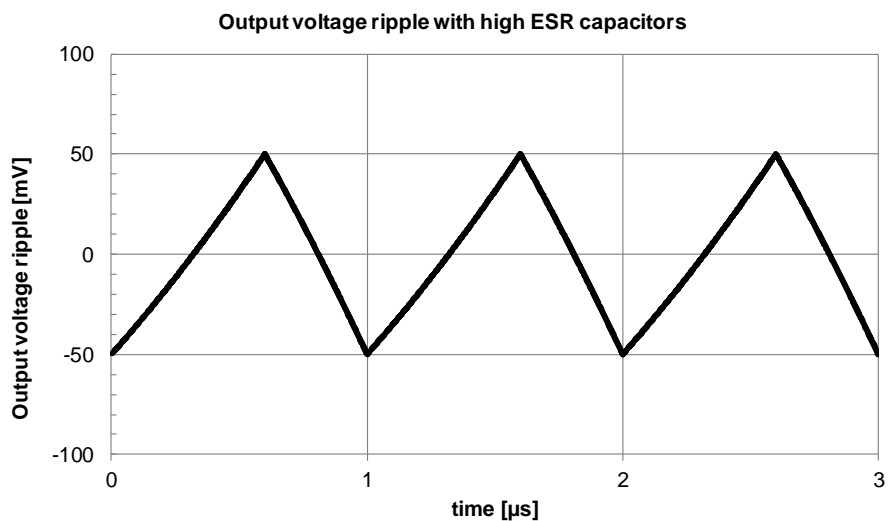
The use of very low ESR capacitors leads to an output voltage ripple as shown below:



When capacitors with slightly higher ESR are utilized, the dominant parameter which influences the output voltage ripple is just the ESR:

$$ESR \leq \frac{V_{OUT \text{ ripple}}}{\Delta I_L} \quad (7)$$

Consequently the shape of the output voltage ripple changes, as shown below:



171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



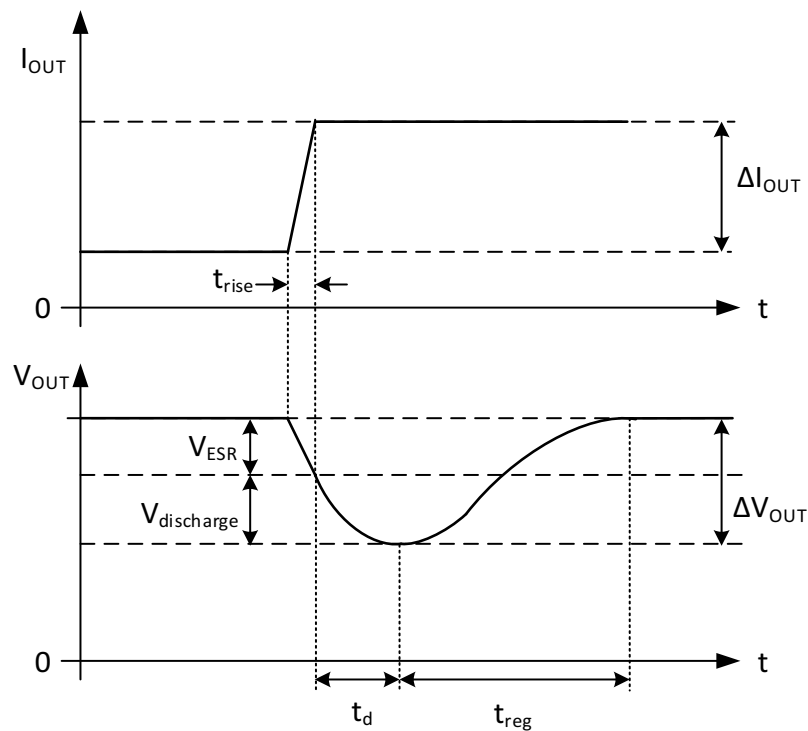
#### Selection by load step requirements

The output voltage is also affected by load transients (see picture below).

When the output current transitions from a low to a high value, the voltage at the output capacitor ( $V_{OUT}$ ) drops. This involves two contributing factors. One is caused by the voltage drop across the ESR ( $V_{ESR}$ ) and depends on the slope of the rising edge of the current step ( $t_{rise}$ ). For low ESR values and small load currents, this is often negligible. It can be calculated as follows:

$$V_{ESR} = ESR \cdot \Delta I_{OUT} \quad (8)$$

Where  $\Delta I_{OUT}$  is the load step, as shown in the picture below (simplified: no voltage ripple is shown).



The second contributing factor is the voltage drop due to discharge of the output capacitor, which can be estimated as:

$$V_{discharge} = \frac{\Delta I_{OUT} \cdot t_d}{2 \cdot C_{OUT}} \quad (9)$$

In a current mode architecture the  $t_d$  is strictly related to the bandwidth of the regulation loop and influenced by the  $C_{OUT}$  (increasing  $C_{OUT}$ , the  $t_d$  increases as well).



171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



In order to choose the value of the output capacitor, the following steps should be utilized:

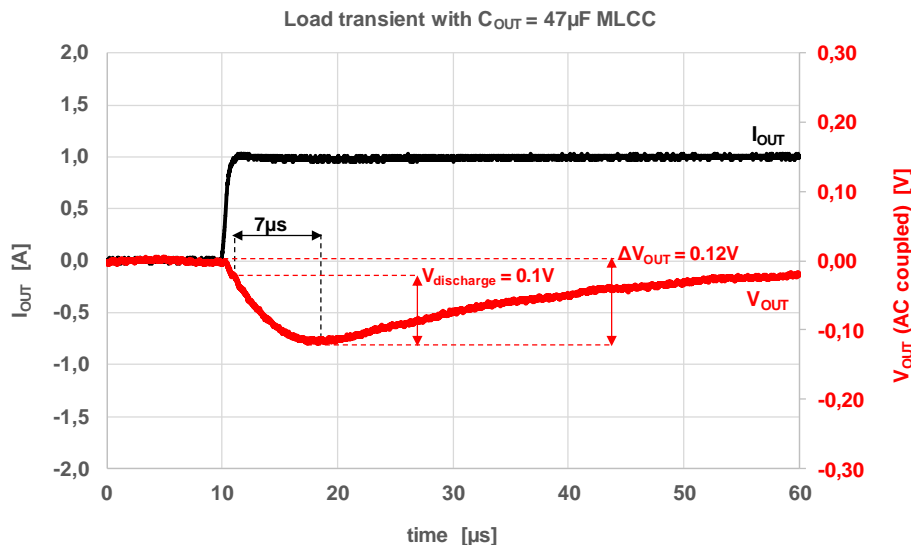
1. According to the operating conditions ( $V_{IN}$ ,  $V_{OUT}$  and  $f_{sw}$ ), select the minimum  $C_{OUT}$  recommended in table on page 35.
2. Measure  $t_d$ .
3. Calculate the appropriate value of  $C_{OUT}$  for the maximum voltage drop  $V_{discharge}$  allowed at a defined load step, using the following equation (10), derived from equation (9):

$$C_{OUT} \geq \frac{\Delta I_{OUT} \cdot t_d}{2 \cdot V_{discharge}} \quad (10)$$

4. As above mentioned, changing  $C_{OUT}$  affects also  $t_d$ . Therefore a new measurement should be performed and, if necessary, the step 2 and 3 should be repeated (it is an iterative process and few steps could be required).

**Example:**  $V_{IN} = 5V$ ,  $V_{OUT} = 3.3V$ ,  $\Delta I_{OUT} = 1A$ ,  $f_{sw} = 1.5MHz$ ,  $\Delta V_{OUT} < 0.1V$ .

According to the table on page 35, an output MLCC of  $47\mu F$  would be necessary. After mounting this capacitor, the load transient should be performed and the  $t_d$  measured (see picture below).



The  $\Delta V_{OUT} = 0.12V$  and  $t_d = 7\mu s$ . It is important to remind that the  $\Delta V_{OUT}$  includes also the voltage drop during  $t_{rise}$ , mainly due to the ESR ( $V_{ESR} = 20mV$ , see picture above). In order to achieve the desired maximum  $\Delta V_{OUT}$ , the  $V_{discharge}$  should be below  $0.06V$ . Using the equation (9), the minimum required output capacitor is:

$$C_{OUT} \geq \frac{1A \cdot 7\mu s}{2 \cdot 0.06V} = 58\mu F$$

To achieve the calculated value of  $C_{OUT}$  an additional MLCC of  $47\mu F$  is mounted in parallel (considering the lower effective capacitance due to DC biasing).

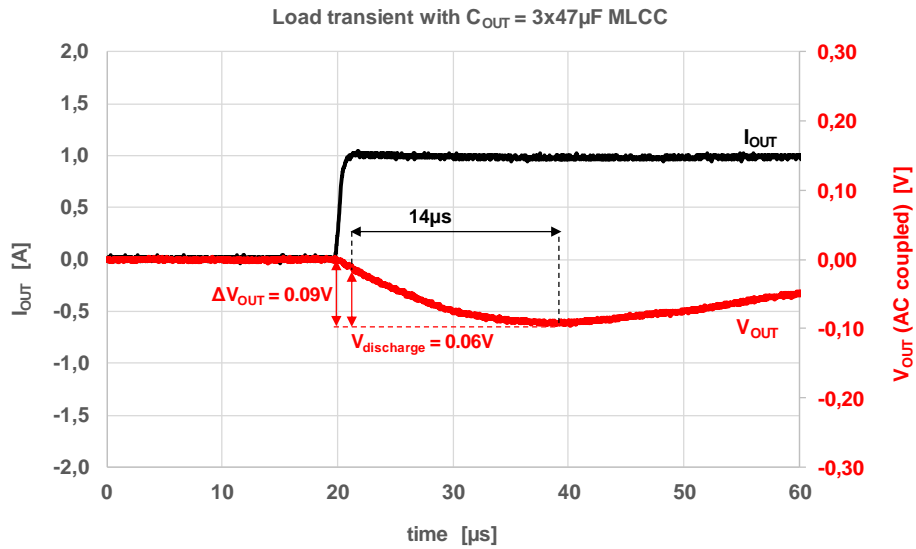
171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



Nevertheless, as indicated in point 4, one or more measurements should be performed in order to find the most suitable value of  $C_{OUT}$ . After some iterations, the most suitable output capacitance is determined as a combination of three MLCC (47 $\mu$ F each one). The final result is shown in the picture below:



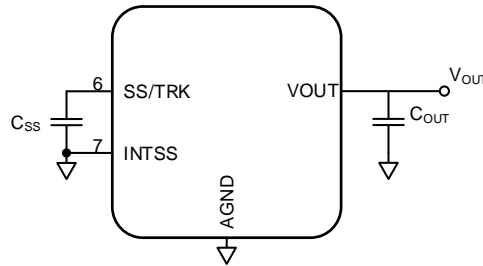
171020302

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**VDRM** – Variable Step Down Regulator Module



**Step 5 Select soft-start capacitor (C<sub>SS</sub>)**

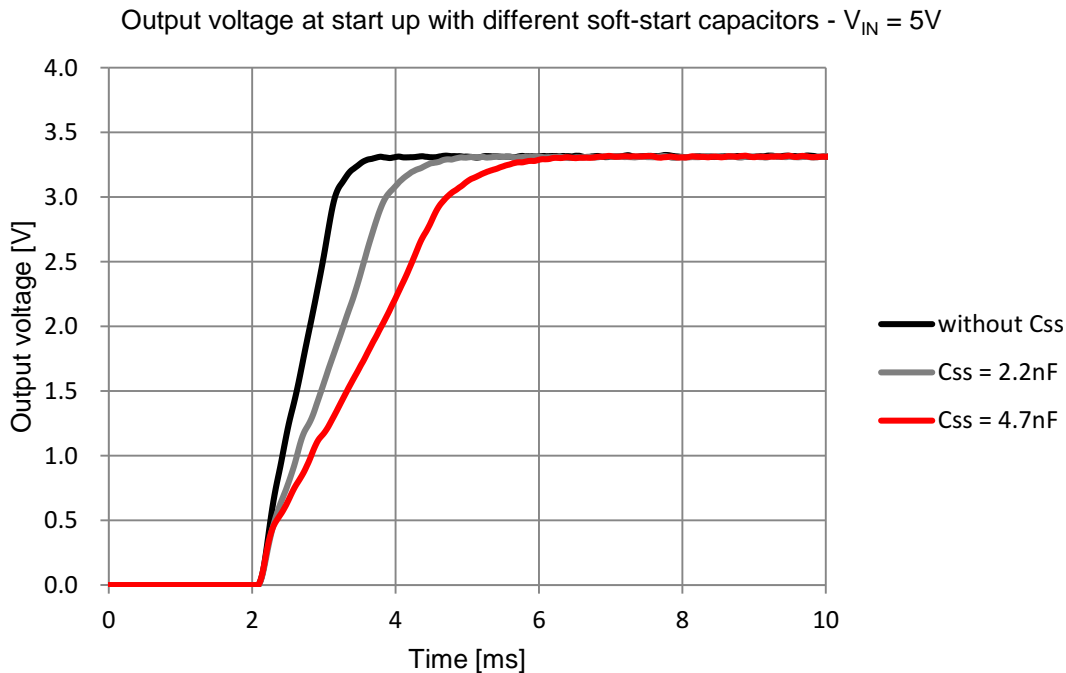
Connecting the INTSS pin to AGND and leaving SS/TRK pin open enables the internal soft-start capacitor with a soft-start interval of approximately 1 ms. Adding additional capacitance between the SS/TRK pin and AGND increases the soft-start time according to the table below. There is no maximum value limit for C<sub>SS</sub>.



C <sub>SS</sub> [nF]	Open	2.2	4.7	10	15	22	27
Soft-start [ms]	~1	~2	~3	~4	~6	~9	~10

The values in the table have been measured at room temperature under full load condition and gives an indication of the soft-start duration.

The diagram below illustrates how the slope of the output voltage changes according to the different soft-start settings. It is important to highlight that the implementation of the soft-start (also without the external C<sub>SS</sub>, a default soft-start capacitor is internally present) prevents the output voltage from experiencing overshoots.



171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module

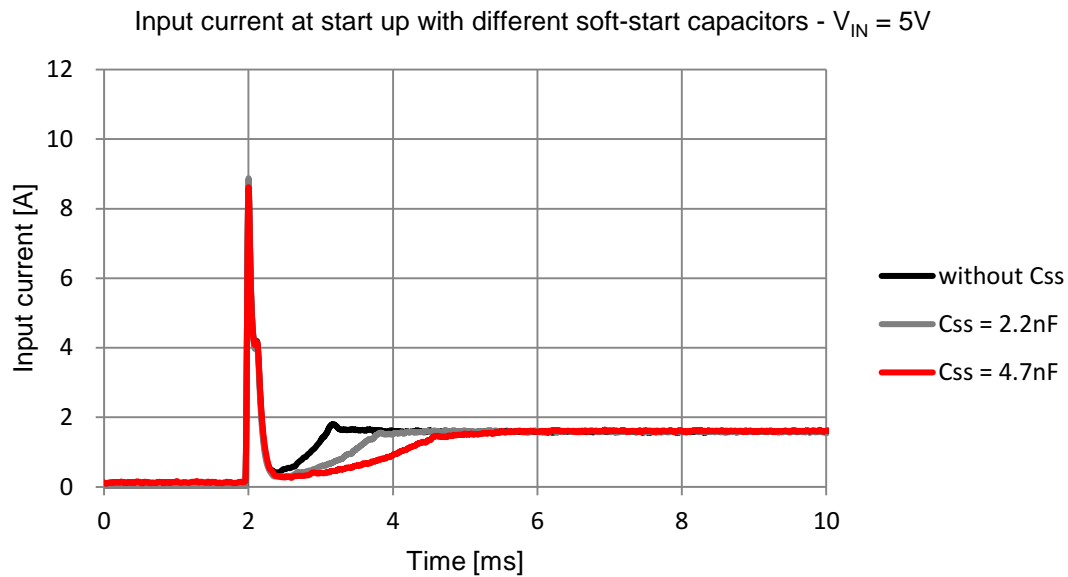


The curves below show a comparison among the input currents under three different soft-start conditions:

- Default soft-start (without any additional external capacitor)
- Soft-start with two different values of  $C_{SS}$ .

The first peak (same for any condition) is due to the initial charge of the capacitors at the input ( $C_{IN}$ ). This current peak is not affected by the soft-start. Therefore it can't be reduced by different soft-start capacitor values.

The right part of the diagram shows the smooth rise of the input current during the start-up. The different slope of the rising edge of the currents is defined by the different soft-start durations.



# 171020302

## MagI<sup>3</sup>C Power Module VDRM – Variable Step Down Regulator Module

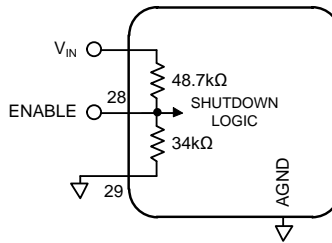


### Step 6 Select undervoltage lockout divider

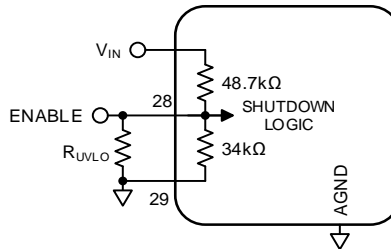
#### Pin 29 connected to analog ground

This connects the internal undervoltage lockout resistor divider. The enable rising threshold is typ. 1.25V. The enable falling threshold is at 1V max. Use at least 10% safety tolerance. For 3.3V input voltage use a rising threshold below 3V. This threshold is attainable by leaving pin 29 open. An external undervoltage lockout resistor will set the rising threshold below 3V.

$V_{IN(UVLO)}$ rising threshold typ. [V]	3.14V
Hysteresis [mV]	300



#### in 29 connected to AGND with additional resistor to adjust undervoltage lockout.



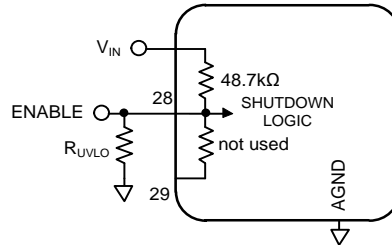
$V_{IN(UVLO)}$ rising threshold typ. [V]	3.25	3.5	3.75	4.0	4.25	4.5	4.75
$R_{UVLO}$ [kΩ]	294	133	86.6	63.4	49.9	42.2	35.7
Hysteresis [mV]	325	335	345	355	365	375	385

171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



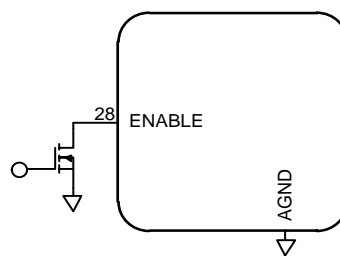
Pin 29 open with additional resistor to adjust undervoltage lockout for lower values.



$V_{IN(UVLO)}$ rising threshold typ. [V]	3.0	2.75	2.5	2.25
$R_{UVLO}$ [kΩ]	34.0	39.7	47.5	60.4
Hysteresis [mV]	170	156	142	126

**Step 7 Enable**

The ENABLE pin provides electrical on/off control of the device. Once the ENABLE pin voltage exceeds the threshold voltage, the device starts operation. If the ENABLE pin voltage is pulled below the threshold voltage, the regulator stops switching and enters low shutdown current state. Apply a voltage  $\leq 1V$  to the enable pin to disable the device. Left open or set to  $\geq 1.5V$  will enable the device. When manually disabling during lab tests, use short leads to connect to AGND of the module. If the logic driver is not close to the ENABLE pin of the module, use a transistor (as shown below) to prevent the noise from disturbing the proper ENABLE/DISABLE function.



171020302

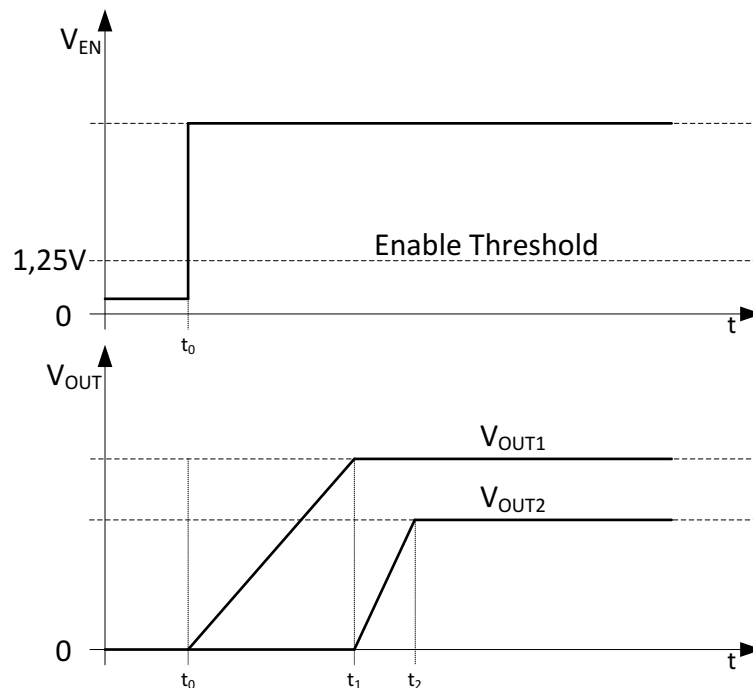
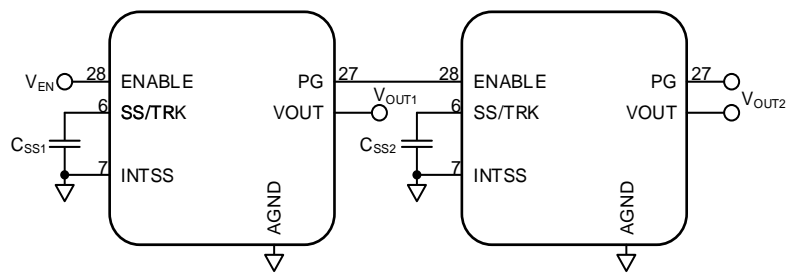
**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**Step 8** Voltage sequencing & tracking

**Sequencing**

Many of the common power supply sequencing methods can be implemented using the SS/TRK, ENABLE and PG pins. The sequential voltage tracking is illustrated below using two devices. The PG pin of the first device is connected to the ENABLE pin of the second device which enables the second power supply once the primary supply reaches regulation. Both modules can apply different slopes of the output voltage during start by selecting the individual soft-start capacitors accordingly.



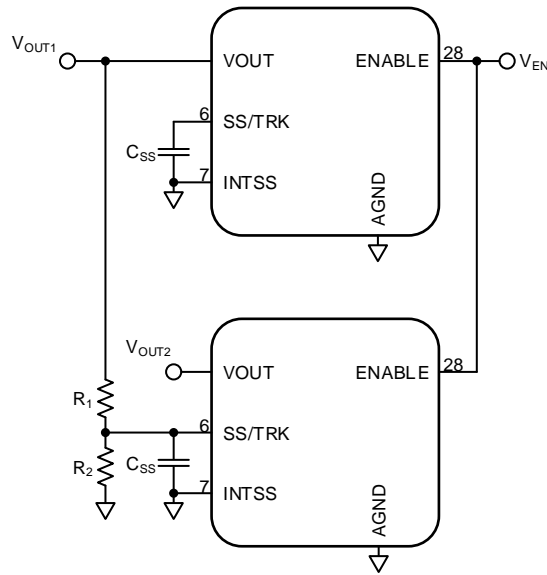
171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**Simultaneous tracking**

Simultaneous power supply sequencing can be implemented by connecting the resistor network of R<sub>1</sub> and R<sub>2</sub> as shown below to the output of the power supply that needs to be tracked or to another voltage reference source.



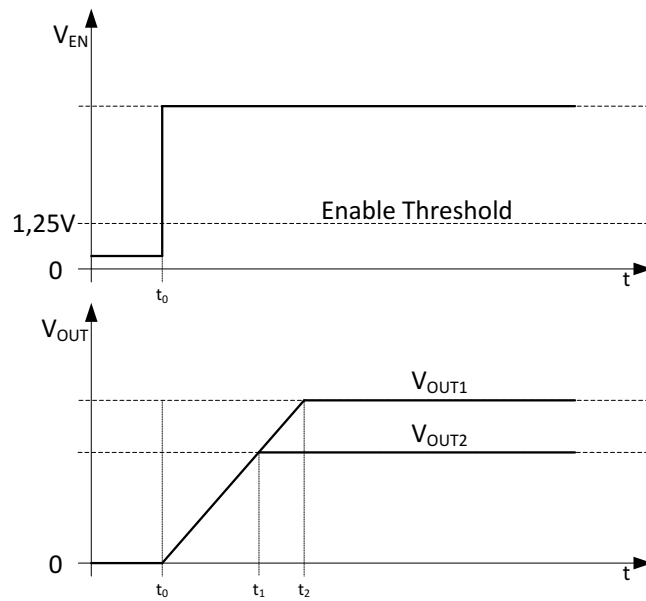
$$R_1 = \frac{V_{OUT2} \cdot 12.6}{V_{REF}} \text{ (k}\Omega\text{)} \quad (10)$$

$$R_2 = \frac{V_{REF} \cdot R_1}{V_{OUT2} - V_{REF}} \text{ (k}\Omega\text{)} \quad (11)$$



171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



171020302

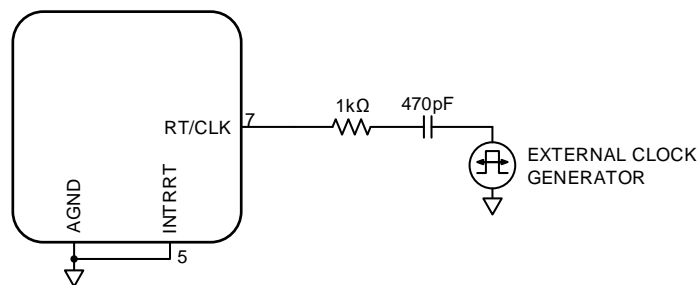
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**VDRM** – Variable Step Down Regulator Module



**Step 9 Synchronizing with an external clock**

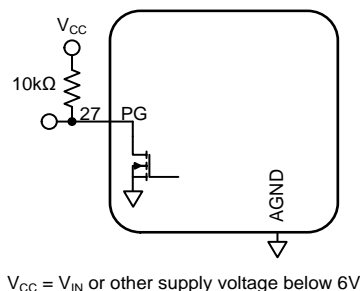
An internal phase locked loop (PLL) has been implemented to allow synchronization between 500 kHz and 2 MHz, and to easily switch from RT mode to CLK mode. To implement the synchronization feature, connect a square wave clock signal to the RT/CLK pin with a minimum pulse width of 75 ns. The maximum clock pulse width must be calculated using Equation 9. The clock signal amplitude must transition lower than 0.4 V and higher than 2.2 V. The start of the switching cycle is synchronized to the falling edge of RT/CLK pin. For applications requiring both RT mode and CLK mode, configure the device as shown in the figure below. Before the external clock is present, the device works in RT mode and the switching frequency is set by the RT resistor ( $R_{RT}$ ). When the external clock is present, the CLK mode overrides the RT mode. The device switches from RT mode to CLK mode and the RT/CLK pin becomes high impedance as the PLL starts to lock onto the frequency of the external clock. The device will lock to the external clock frequency approximately 15  $\mu$ s after a valid clock signal is present. It is not recommended to switch from CLK mode back to RT mode because the internal switching frequency drops to a lower frequency before returning to the switching frequency set by the RT resistor.

$$\text{Maximum clock pulse width} = \frac{0.75 \cdot \left(1 - \frac{V_{OUT}}{V_{INMIN}}\right)}{f_{SW}} \quad (12)$$



**Step 10 Power Good**

The PG pin is an open drain output. Once the voltage on the SENSE+ pin is between 93% and 107% of the nominal value, the PG pin pull-down is released and the pin floats. The recommended pull-up resistor value is between 10 k $\Omega$  and 100 k $\Omega$  to a voltage source that is 6 V or less. The PG pin is in a defined state once  $V_{IN}$  is higher than 1.2 V, but with reduced current sinking capability. The PG pin achieves full current sinking capability once the  $V_{IN}$  pin is above 2.95V. The PG pin is pulled low when the voltage on SENSE+ is lower than 91% or higher than 109% of the set output voltage. Also, the PG pin is pulled low if the input UVLO or thermal shutdown is asserted, or if the ENABLE pin is pulled low.



**171020302****MagI<sup>3</sup>C** Power Module  
VDRM – Variable Step Down Regulator Module**PROTECTIVE FEATURES****Over Temperature Protection (OTP)**

The junction temperature of the MagI<sup>3</sup>C Power Module should not be allowed to exceed its maximum ratings. Thermal protection is implemented by an internal thermal shutdown circuit which activates at 175°C (typ) causing the device to enter a low power standby state. In this state the main MOSFET remains off causing  $V_{OUT}$  to fall, and additionally the  $C_{SS}$  capacitor is discharged to ground. Thermal protection helps prevent catastrophic failures due to accidental device overheating. When the junction temperature falls below 160°C the SS pin is released,  $V_{OUT}$  rises smoothly, and normal operation resumes. Applications requiring maximum output current, especially those at high input voltages, may require additional derating at elevated temperatures.

**Overcurrent Protection (OCP)**

For protection against load faults, the MagI<sup>3</sup>C Power Module incorporates cycle-by-cycle current limiting (see  $I_{OCP}$  in "Electrical Specification" on page 7). During an overcurrent condition the output current is limited and the output voltage is reduced. As the output voltage drops more than 9% below the set point, the PG signal is pulled low. If the output voltage drops more than 25%, the switching frequency is reduced to reduce power dissipation within the device. When the overcurrent condition is removed, the output voltage returns to the nominal voltage.

**Short Circuit Protection (SCP)**

The short circuit protection is realized via cycle-by-cycle current limiting. The short circuit protection is continuous with a recovery at the following switching cycle if the short circuit condition is removed.

**Output Overvoltage Protection (OVP)**

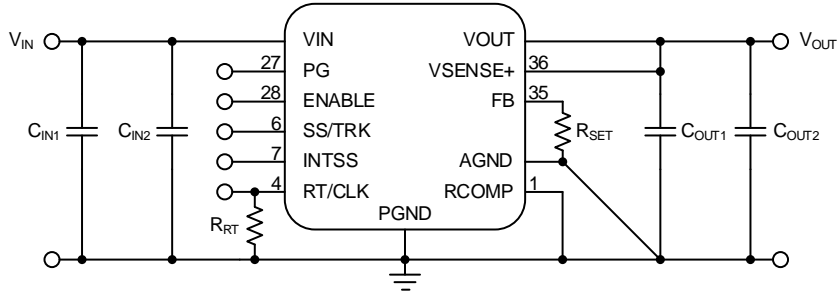
The device incorporates an overvoltage protection to minimize output voltage overshoot when recovering from output fault conditions. When the output voltage reaches the upper trip point of 109% of the voltage programmed with the feedback resistor divider, the high-side MOSFET is disabled to prevent further output voltage rise caused by the module itself. When the output voltage reaches the lower trip point of 105% of the programmed output voltage, the high-side MOSFET will be turned on again at the next switching cycle.

# 171020302

## MagI<sup>3</sup>C Power Module VDRM – Variable Step Down Regulator Module



### TYPICAL SCHEMATIC



INPUT	OUTPUT	C <sub>IN2</sub>	C <sub>IN1</sub>	R <sub>RT</sub>	R <sub>SET</sub>	C <sub>OUT1</sub>	C <sub>OUT2</sub>
5V	3.3V	220μ	47μF X5R	174kΩ	459Ω	47μF X5R	-
5V	2.5V	220μ	47μF X5R	174kΩ	673Ω	47μF X5R	47μ X5R
5V	1.8V	220μ	47μF X5R	348kΩ	1150Ω	47μF X5R	47μ X5R
5V	1.5V	220μ	47μF X5R	348kΩ	1650Ω	47μF X5R	100μF
5V	1.2V	220μ	47μF X5R	715kΩ	2870Ω	47μF X5R	100μF
5V	1.0V	220μ	47μF X5R	715kΩ	5830Ω	47μF X5R	100μF
5V	0.8V	220μ	47μF X5R	1200kΩ	Open	47μF X5R	100μF
3.3V	1.8V	220μ	47μF X5R	348kΩ	1150Ω	47μF X5R	47μ X5R
3.3V	1.5V	220μ	47μF X5R	348kΩ	1650Ω	47μF X5R	100μF
3.3V	1.2V	220μ	47μF X5R	715kΩ	2870Ω	47μF X5R	100μF
3.3V	1.0V	220μ	47μF X5R	715kΩ	5830Ω	47μF X5R	100μF
3.3V	0.8V	220μ	47μF X5R	1200kΩ	Open	47μF X5R	100μF

C<sub>IN2</sub> and C<sub>OUT2</sub> ≥ 100μF are polymer electrolytic types.

171020302

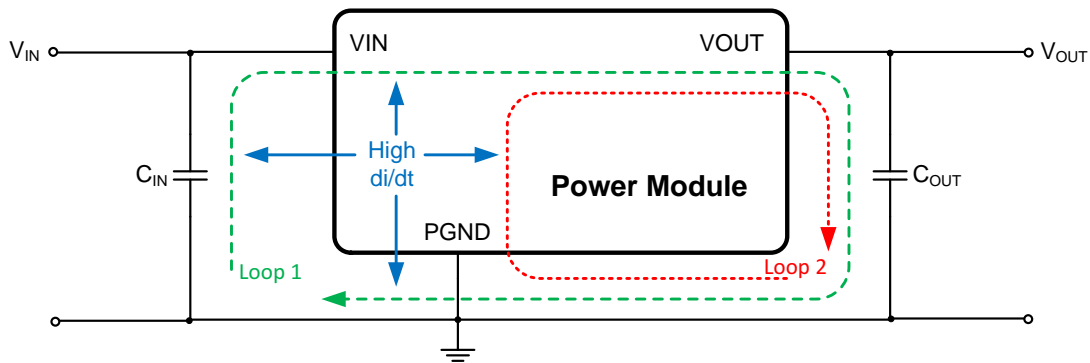
**Magl<sup>3</sup>C Power Module**  
**VDRM – Variable Step Down Regulator Module**



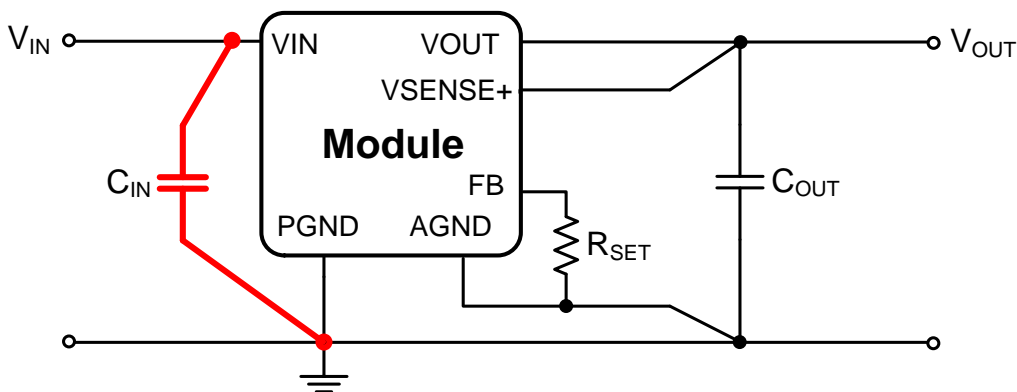
**LAYOUT RECOMMENDATION**

PCB layout is an important part of DC-DC converter design. Poor board layout can interfere with the performance of a DC-DC converter and surrounding circuitry by contributing to EMI, ground bounce and resistive voltage drop in the traces. These can send erroneous signals to the DC-DC converter resulting in poor regulation or instability. Good layout can be implemented by following five simple design rules.

**1: Minimize area of switched current loops**



Target is to identify the paths in the system which have discontinuous current flow. They are the most critical ones because they act as an antenna and cause observable high frequency noise (EMI). The easiest approach to find the critical paths is to draw the high current loops during both switching cycles and identify the sections which do not overlap. They are the ones where no continuous current flows and high di/dt is observed. Loop1 is the current path during the ON-time of the High-Side MOSFET. Loop2 is the current path during the OFF-time of the High-Side MOSFET.



Based on those considerations, the path of the input capacitor  $C_{IN}$  is the most critical one to generate high frequency noise on  $V_{IN}$ . Therefore place  $C_{IN}$  as close as possible to the Magl<sup>3</sup>C power module  $V_{IN}$  and  $PGND$  pins. This will minimize the high di/dt area and reduce radiated EMI. Additionally, grounding for both the input and output capacitor should consist of a localized top side plane that connects to the  $PGND$  pins.

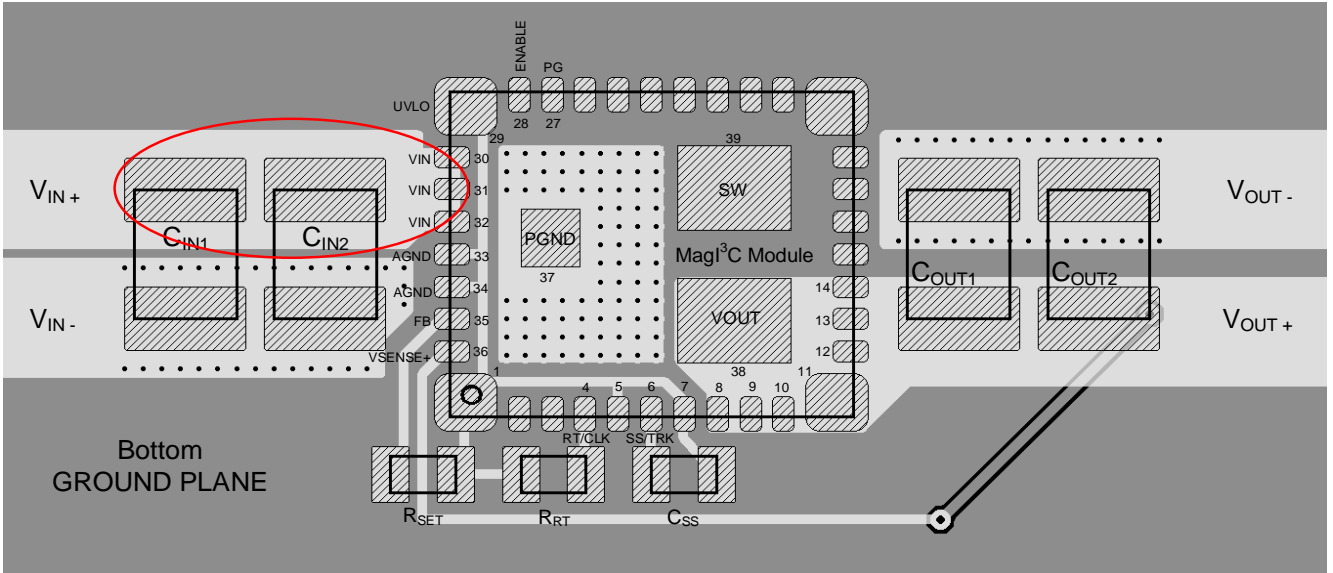
171020302

**MagI<sup>3</sup>C Power Module**  
**VDRM – Variable Step Down Regulator Module**



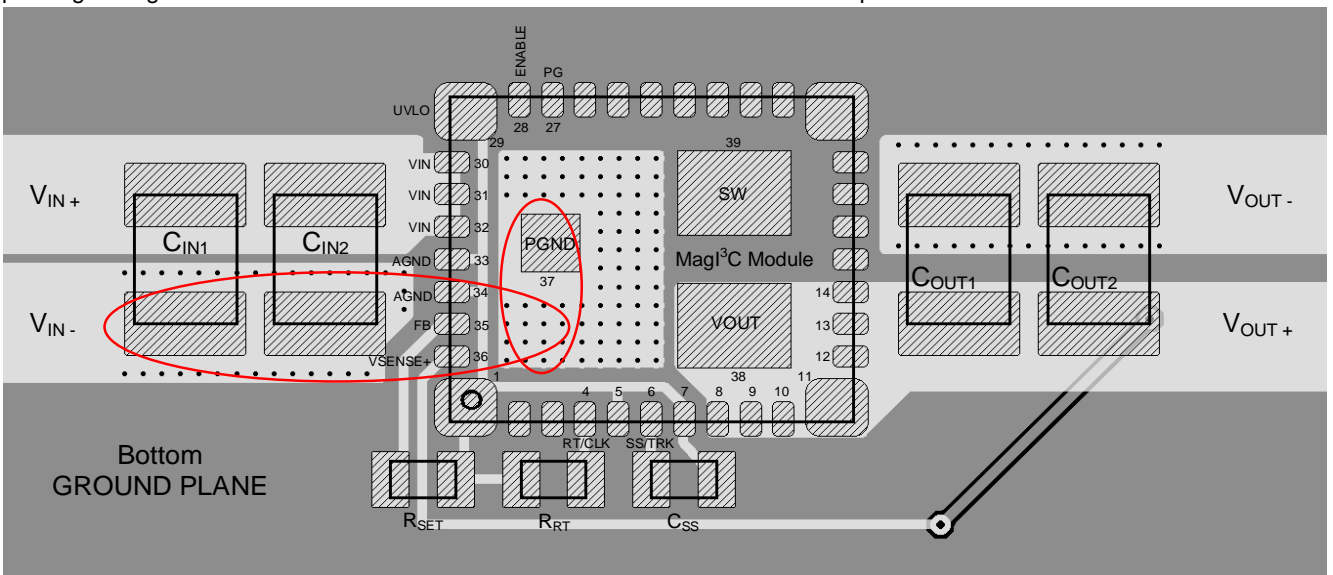
The placement of the input capacitors is highlighted in the following pictures of the evaluation board.

The positive terminal of  $C_{IN1}$  and  $C_{IN2}$  need to be very close to the VIN pins of the power module.



PCB color coding:  Top layer  Bottom layer

The negative terminal of  $C_{IN1}$  and  $C_{IN2}$  need to be very close to the PGND pad of the power module. The ground path is passing through the vias at the  $C_{IN}$  terminals and thermal vias around the PGND pad.



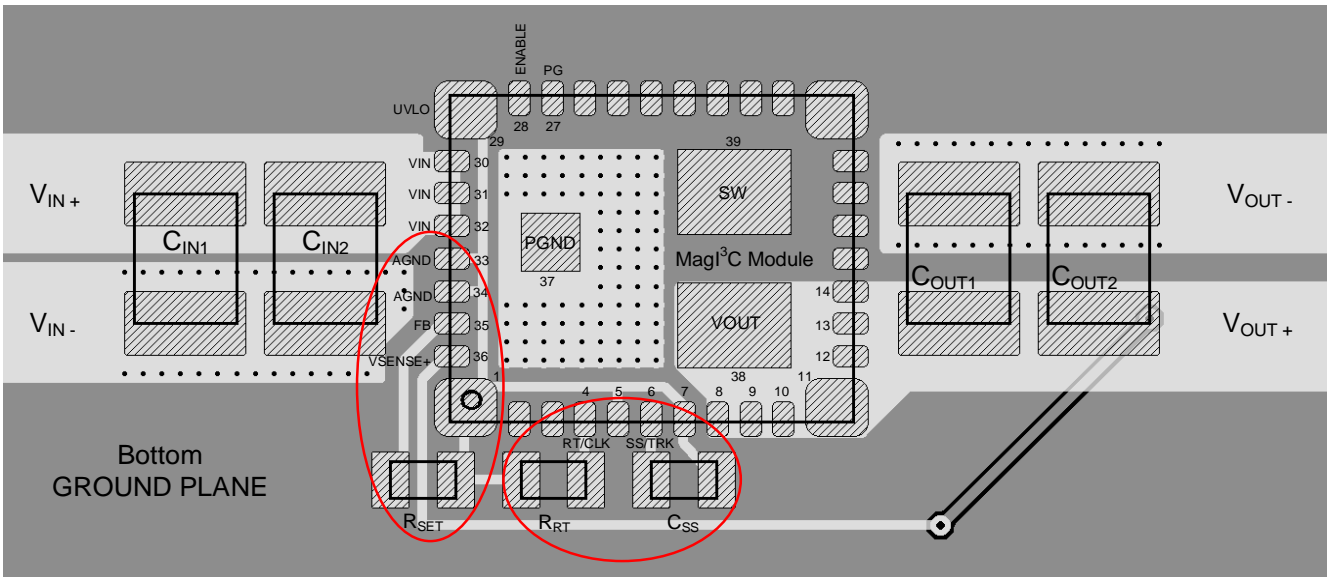
171020302

**MagI<sup>3</sup>C Power Module**  
**VDRM – Variable Step Down Regulator Module**



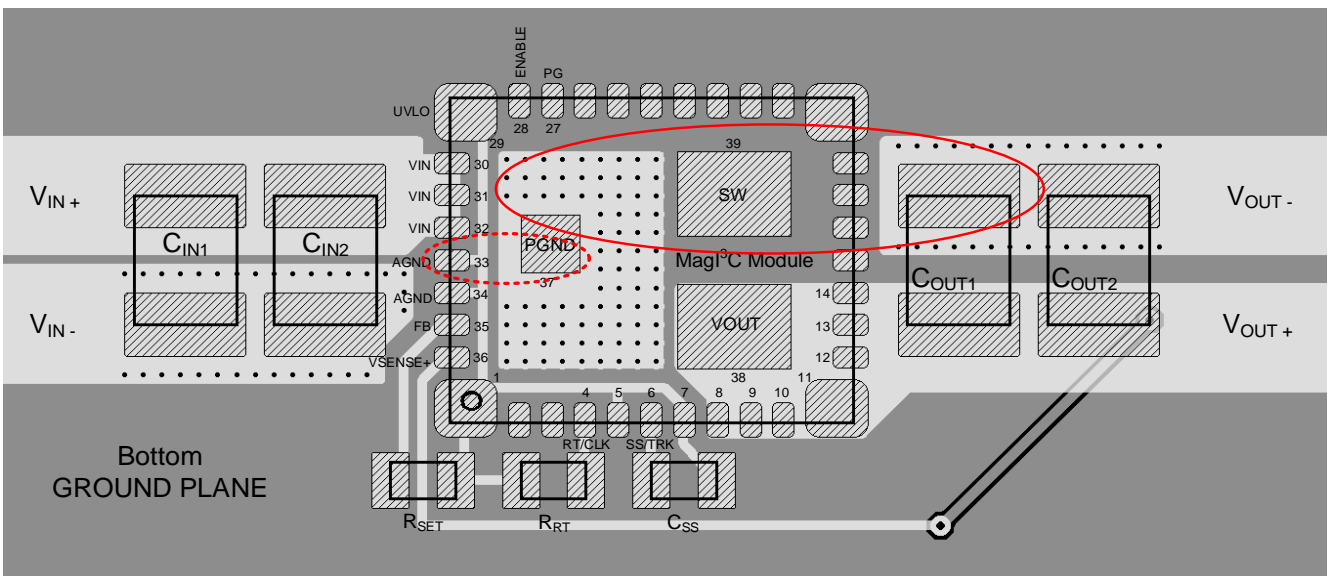
**2: Analog Ground (AGND) connections**

The ground connections for the clock setting resistor ( $R_{RT}$ ), soft-start capacitor ( $SS/TRK$ ), output voltage setting resistor ( $R_{SET}$ ) and enable components should be routed to the AGND pins of the device. If not properly handled, poor grounding can result in degraded load regulation or erratic output voltage ripple behavior. Place  $R_{RT}$ , and  $C_{SS}$  close to their respective pins.



**3: Analog Ground (AGND) to Power Ground (PGND) connections**

The AGND is **internally connected** to PGND at a low noise node. The output ground current is flowing from the PGND pad through the ground plane through the ground terminal of the first output capacitor. Due to its very low ripple it will not inject noise in the ground plane.



Module Internal connection:

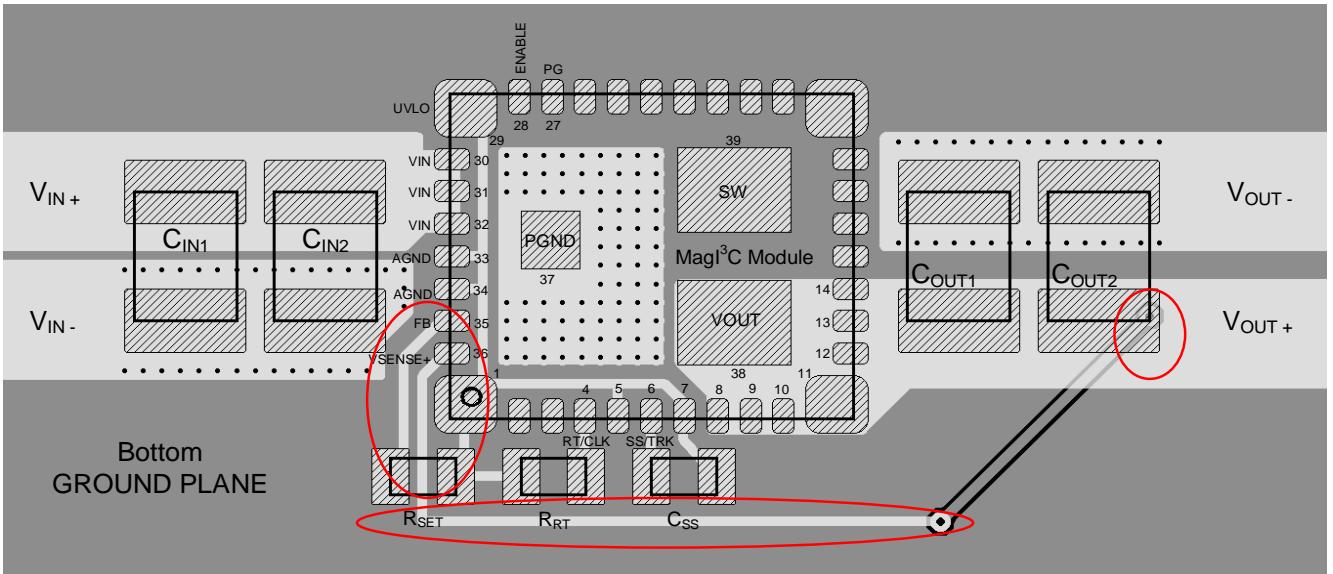
171020302

**Magi<sup>3</sup>C Power Module**  
**VDRM – Variable Step Down Regulator Module**



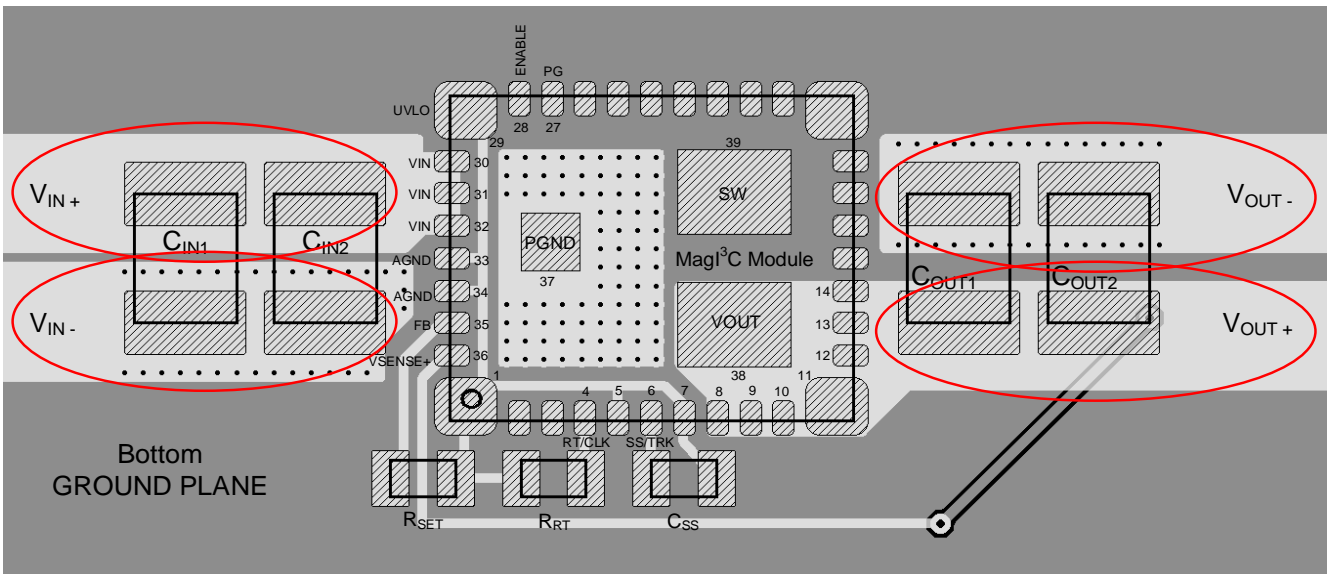
**4: Feedback layout**

The feedback resistor,  $R_{SET}$  should be located close to the FB pin. Since the FB node is high impedance, maintain the trace thickness small. The traces from  $R_{SET}$  should be routed away from the body of the Magi<sup>3</sup>C power module to minimize noise pickup. Connect the feedback trace at the positive terminal of the last output capacitor ( $C_{OUT2}$ ). As this is the node of lowest noise.



**5: Make input and output bus connections as wide as possible**

This reduces any voltage drops on the input or output of the converter and maximizes efficiency.





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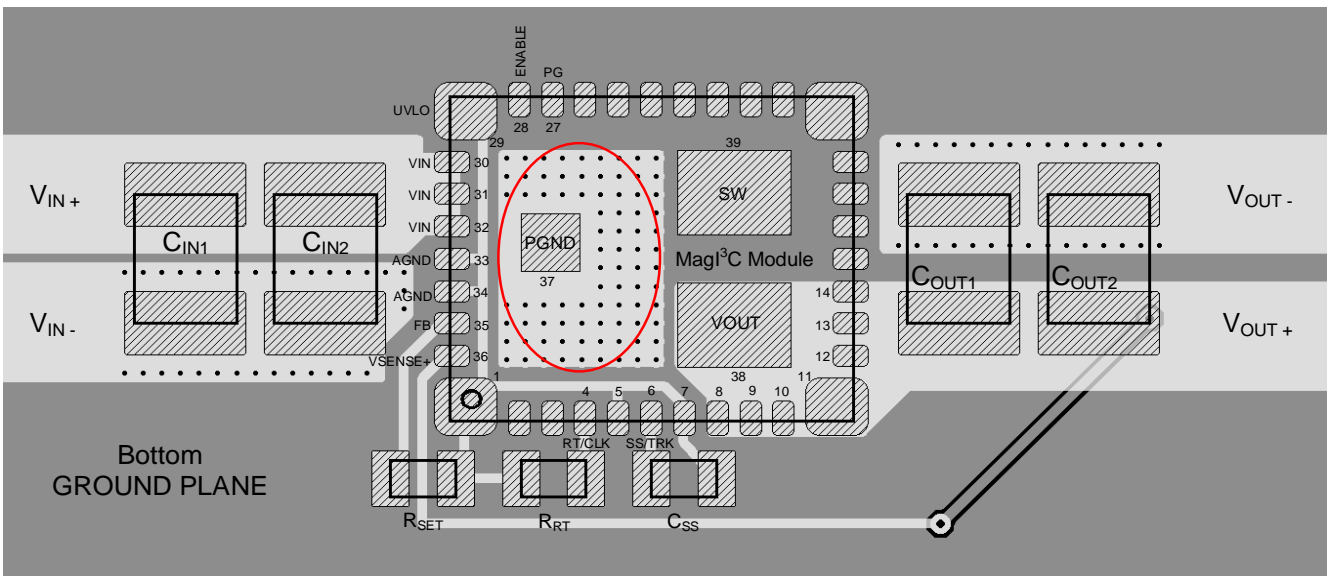
**Magi<sup>3</sup>C Power Module**  
**VDRM – Variable Step Down Regulator Module**



**6: Provide adequate device heat-sinking**

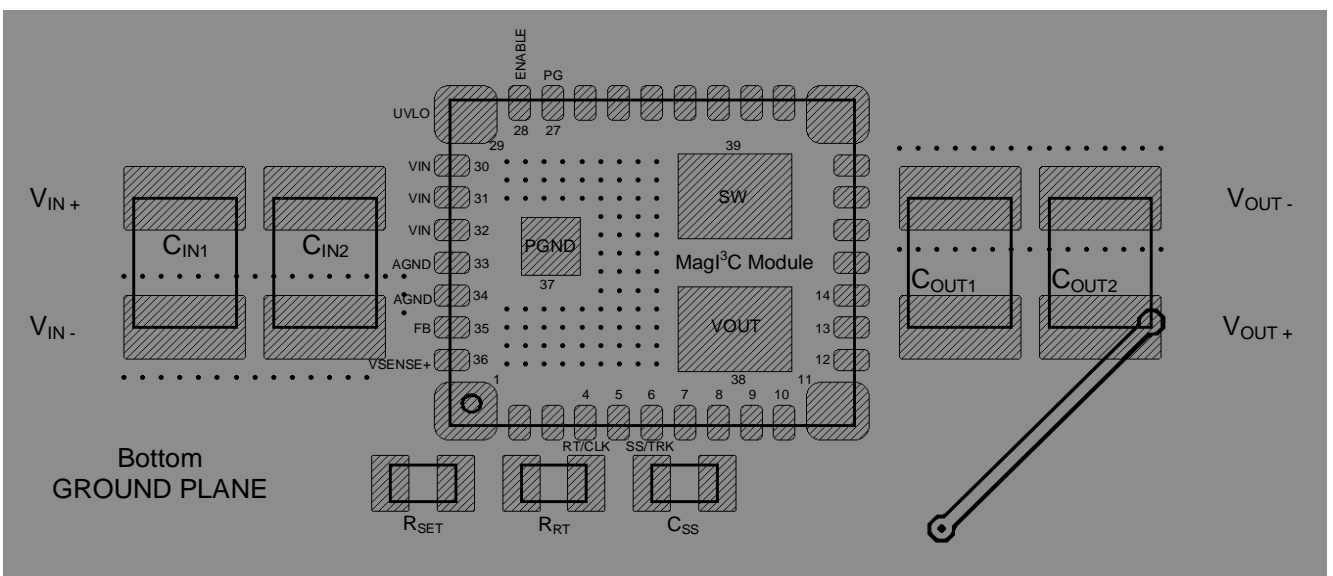
Place a dedicated PGND copper area beneath the Magi<sup>3</sup>C Power Module.

Use an array of heat-sinking vias to connect the PGND pad to the ground plane on the bottom PCB layer. If the PCB has a plurality of copper layers, these thermal vias can also be used to make connection to inner layer heat-spreading ground planes. For best results use a via array as proposed in the picture above with via diameter of 200µm (hole: 100µm) thermal vias spaced 200µm. Ensure enough copper area is used for heat-sinking to keep the junction temperature below 125°C.



**6: Isolate high noise areas**

Place a dedicated solid GND copper area beneath the Magi<sup>3</sup>C Power Module.



171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module

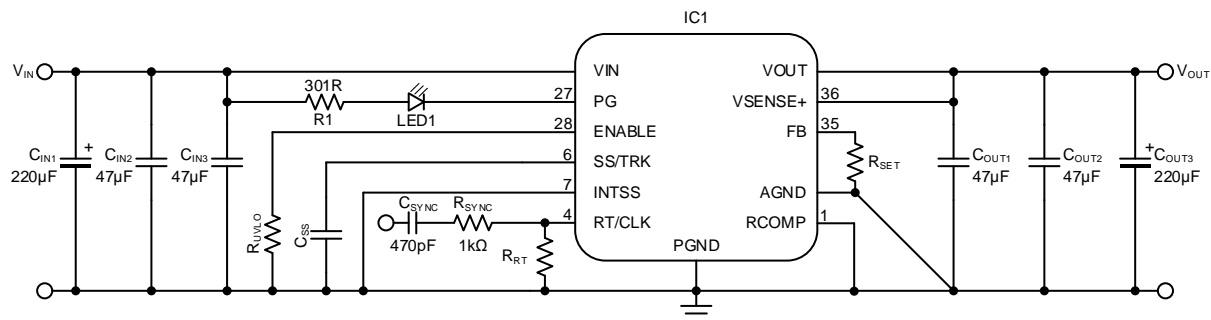


#### EVALUATION BOARD SCHEMATIC (178020302 v1.0)

The board schematic has been developed to be suitable for all conditions of input and output voltage, switching frequency, load current and to achieve optimum load transient response.

The two 47µF multi-layer ceramic capacitors (MLCCs) at the input handle the switching current ripple and support fast load transients preventing the voltage at the VIN pin from dropping, potentially below the UVLO. Two MLCCs in parallel helps reducing further the ESR. The additional 220µF aluminum electrolytic polymer capacitor is mounted as termination of the supply line and provides damping of possible oscillations due to the series resonance circuit represented by the inductance of the supply line and the input capacitance.

The output capacitors should provide a high value of capacitance as well as a low ESR, in order to reduce the output voltage ripple and improving load transient response. This is achieved in this evaluation board by combining two 47µF MLCCs with a 220µF aluminum electrolytic polymer capacitor. The use of two MLCCs in parallel leads to a further reduction of the ESR. Furthermore, the use of two parallel MLCCs at the input and at the output increases the reliability of the system.



#### Operational Requirements

At small  $V_{IN}$  to  $V_{OUT}$  ratio (high duty cycle) the input current will be in a similar range than the output current. Make sure that your supply for the module is capable of high currents (check current limit setting of your power supply). In case your module output voltage  $V_{OUT}$  is set to very low values (for example 0.8V) electronic loads might not be able to work correctly. Use discrete high power resistors instead as a load. Use thick and short leads to the input of the module and to the load. High currents result in additional voltage drops across the cables which decrease the voltage at the load. Measure the input and output voltage directly at the ceramic capacitors at the input and output (test points).

171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module

**Bill of Material**

Designator	Description	Quantity	Order Code	Manufacturer
IC1	MagI <sup>3</sup> C Power Module	1	171020302	Würth Elektronik
C <sub>IN1</sub> , C <sub>OUT3</sub>	Electrolytic polymer capacitor 220µF/10V	2	875105244013	Würth Elektronik
C <sub>IN2</sub> , C <sub>IN3</sub> , C <sub>OUT1</sub> , C <sub>OUT2</sub>	Ceramic chip capacitor 47µF/10V X5R, 1210	4	885012109007	Würth Elektronik
C <sub>SYNC</sub>	Ceramic chip capacitor 470pF/50V NP0/COG	1	885012007007	Würth Elektronik
LED1	LED red	1	150080SS75000	Würth Elektronik
C <sub>SS</sub> , R <sub>UVLO</sub>	Not mounted			
R <sub>SYNC</sub>	1000Ω	1		
R1	301Ω	1		
R <sub>RT</sub>	Set by jumper	1.2 MΩ for f <sub>SW</sub> = 650kHz	1	
		715 kΩ for f <sub>SW</sub> = 750kHz	1	
		348 kΩ for f <sub>SW</sub> = 1MHz	1	
		232kΩ for f <sub>SW</sub> = 1.25MHz	1	
		174kΩ for f <sub>SW</sub> = 1.5MHz	1	
		113kΩ for f <sub>SW</sub> = 2MHz	1	
R <sub>SET</sub>	Set by jumper	5620Ω for V <sub>OUT</sub> = 1.0V	1	
		2870Ω for V <sub>OUT</sub> = 1.2V	1	
		1620Ω for V <sub>OUT</sub> = 1.5V	1	
		1130Ω for V <sub>OUT</sub> = 1.8V	1	
		665Ω for V <sub>OUT</sub> = 2.5V	1	
		453Ω for V <sub>OUT</sub> = 3.3V	1	

171020302

## MagI<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module

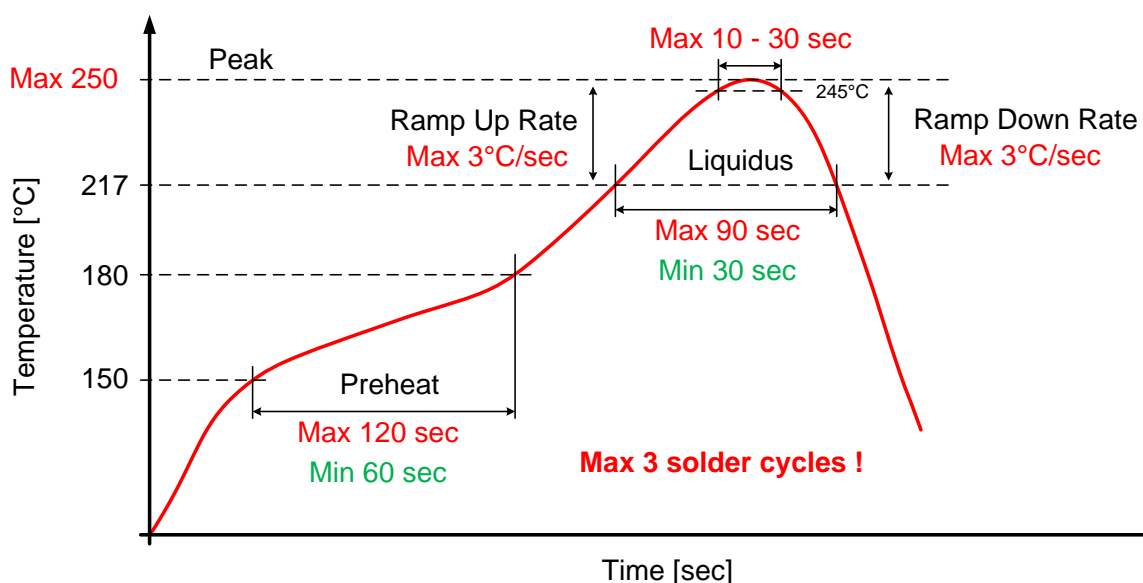


#### HANDLING RECOMMENDATIONS

1. The power module is classified as MSL3 (JEDEC Moisture Sensitivity Level 3) and requires special handling due to moisture sensitivity (JEDEC J-STD033).
2. The parts are delivered in a sealed bag (Moisture Barrier Bags = MBB) and should be processed within one year.
3. When opening the moisture barrier bag check the Humidity Indicator Card (HIC) for color status. Bake parts prior to soldering in case indicator color has changed according to the notes on the card.
4. Parts must be processed after 168 hour (7 days) of floor life. Once this time has been exceeded, bake parts prior to soldering per JEDEC J-STD033 recommendation.

#### SOLDER PROFILE

1. Only Pb-Free assembly is recommended according to JEDEC J-STD020.
2. Measure the peak reflow temperature of the MagI<sup>3</sup>C Power Module in the middle of the top view.
3. Ensure that the peak reflow temperature does not exceed 245°C ±5°C as per JEDEC J-STD020.
4. The reflow time period during peak temperature of 245°C ±5°C must not exceed 30 seconds.
5. Reflow time above liquidus (217°C) must not exceed 90 seconds.
6. Maximum ramp up is rate 3°C per second.
7. Maximum ramp down rate is 3°C per second.
8. Reflow time from room (25°C) to peak must not exceed 8 minutes as per JEDEC J-STD020.
9. **Maximum numbers of reflow cycles is three.**
10. **For minimum risk, solder the module in the last reflow cycle of the PCB production.**
11. For soldering process please consider lead material copper (Cu) and lead finish tin (Sn).
12. For solder paste use a standard SAC Alloy such as SAC 305, type 3 or higher.
13. Below profile is valid for convection reflow only.
14. Other soldering methods (e.g.vapor phase) are not verified and have to be validated by the customer on his own risk

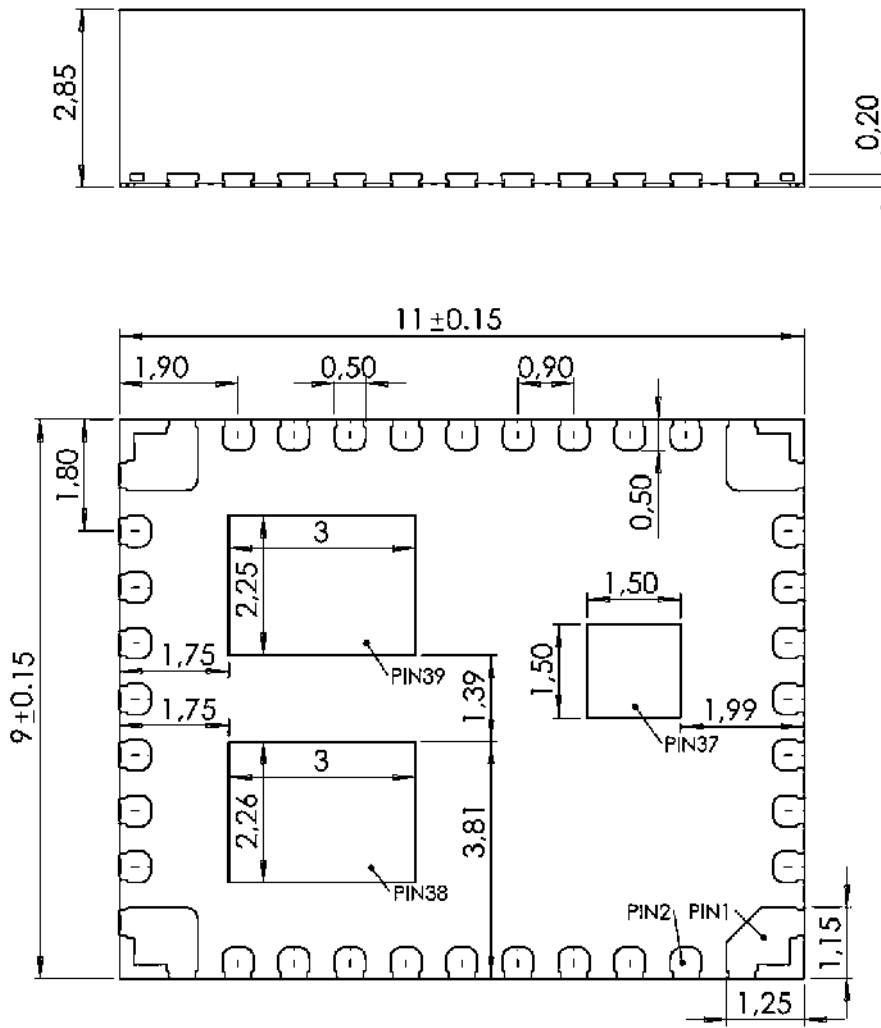


171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**PHYSICAL DIMENSIONS**



Bottom View

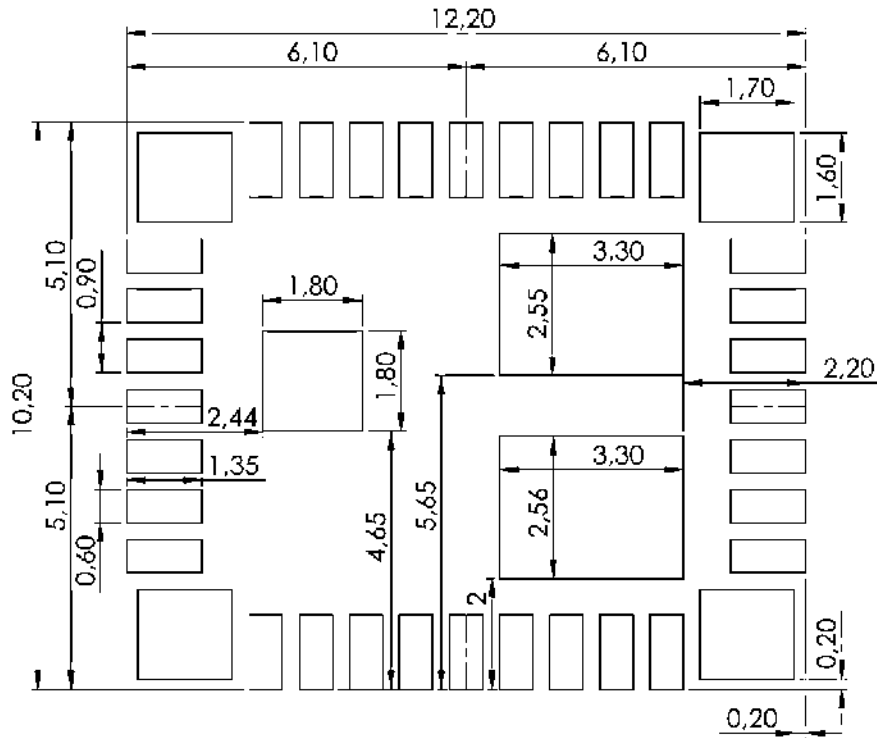
all dimensions in mm

171020302

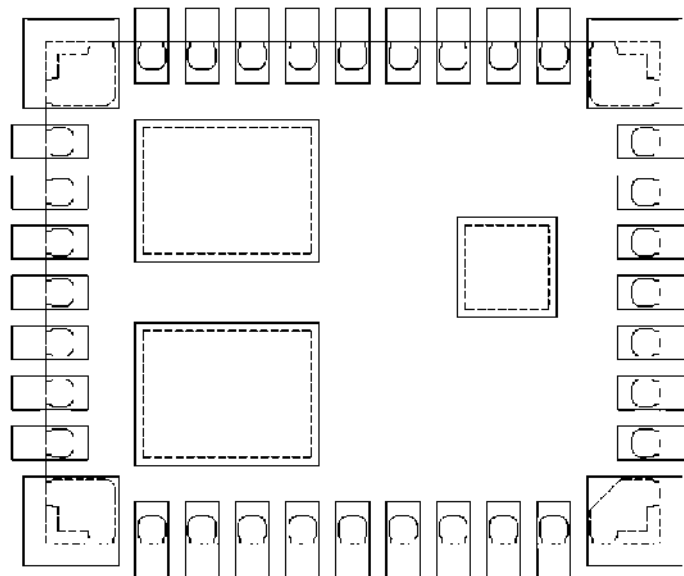
**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**EXAMPLE FOOTPRINT DESIGN**



All dimensions in mm



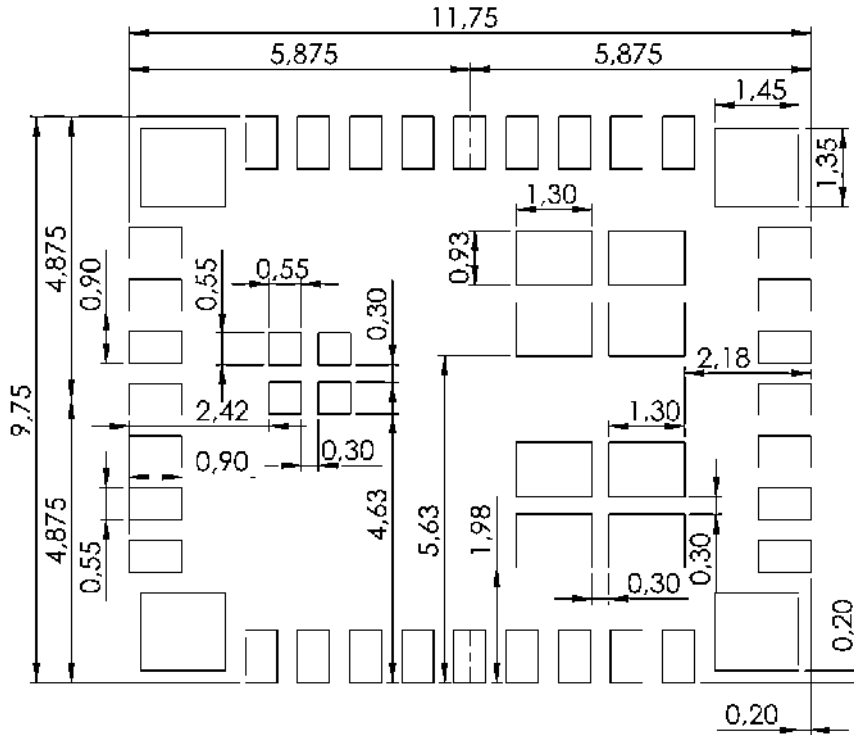
Example footprint with pins

171020302

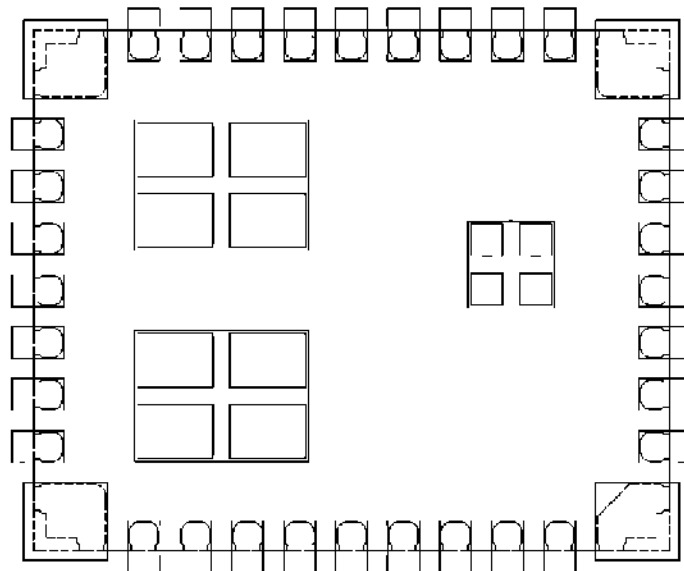
**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



**EXAMPLE SOLDER PASTE STENCIL DESIGN**



All dimensions in mm



Example solder paste stencil with pins  
 Stencil thickness 0.125mm

171020302

**MagI<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



## DOCUMENT HISTORY

Revision	Date	Description	Comment
1.0	May 2016	Release of the final version	
1.1	July 2022	Minor formatting change	Added pin 1 to schematics on page 1, 18, 35 and 41. Adjusted equation for CIN, on page 21. Updated CAUTIONS AND WARNINGS and IMPORTANT NOTES



171020302

**Magl<sup>3</sup>C** Power Module  
**VDRM** – Variable Step Down Regulator Module



### CAUTIONS AND WARNINGS

The following conditions apply to all goods within the product series of Magl<sup>3</sup>C of Würth Elektronik eiSos GmbH & Co. KG:

#### General:

- This electronic component is designed and manufactured for use in general electronic equipment.
- Würth Elektronik must be asked for written approval (following the PPAP procedure) before incorporating the components into any equipment in fields such as military, aerospace, aviation, nuclear control, submarine, transportation (automotive control, train control, ship control), transportation signal, disaster prevention, medical, public information network, etc. where higher safety and reliability are especially required and/or if there is the possibility of direct damage or human injury.
- Electronic components that will be used in safety-critical or high-reliability applications, should be pre-evaluated by the customer.
- The component is designed and manufactured to be used within the datasheet specified values. If the usage and operation conditions specified in the datasheet are not met, the component may be damaged or dissolved.
- Do not drop or impact the components as material of the body, pins or termination may flake apart.
- Würth Elektronik products are qualified according to international standards, which are listed in each product reliability report. Würth Elektronik does not warrant any customer qualified product characteristics beyond Würth Elektronik's specifications, for its validity and sustainability over time.
- All technical specifications for standard products also apply to customer specific products.
- Customer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of Würth Elektronik eiSos GmbH & Co. KG components in its applications, notwithstanding any applications-related information or support that may be provided by Würth Elektronik eiSos GmbH & Co. KG. Customer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Customer will fully indemnify Würth Elektronik eiSos and its representatives against any damages arising out of the use of any Würth Elektronik eiSos GmbH & Co. KG components in safety-critical applications.

171020302

## Magl<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### Product specific:

##### Soldering:

- The solder profile must comply with the technical product specifications. All other profiles will void the warranty
- All other soldering methods are at the customer's own risk.
- Cleaning and Washing:
- Residual washing varnish agent that is used during the production to clean the application might change the characteristics of the body, pins or termination. The washing varnish agent may have a negative effect on the longterm function of the component
- Using a brush during the cleaning process may break the component. Therefore, we do not recommend using a brush during the PCB cleaning process.

##### Potting and Coating:

- If the component is potted in the customer application, the potting material might shrink or expand during and after hardening. Shrinking could lead to an incomplete seal, allowing contaminants into the component. Expansion could damage the components or parts of it. We recommend a manual inspection after potting to avoid these effects.
- Conformal coating may affect the product performance.
- Storage Conditions:
- A storage of Würth Elektronik products for longer than 12 months is not recommended. Within other effects, the terminals may suffer degradation, resulting in bad solderability. Therefore, all products shall be used within the period of 12 months based on the day of shipment.
- Do not expose the components to direct sunlight.
- The storage conditions in the original packaging are defined according to DIN EN 61760-2.
- For a moisture sensitive component, the storage condition in the original packaging is defined according to IPC/JEDEC-J-STD-033. It is also recommended to return the component to the original moisture proof bag and reseal the moisture proof bag again
- ESD prevention methods need to be followed for manual handling and processing by machinery.
- The storage conditions stated in the original packaging apply to the storage time and not to the transportation time of the components.

##### Packaging:

- The packaging specifications apply only to purchase orders comprising whole packaging units. If the ordered quantity exceeds or is lower than the specified packaging unit, packaging in accordance with the packaging specifications cannot be ensured.

##### Handling:

- Violation of the technical product specifications such as exceeding the absolute maximum ratings will void the warranty and also the conformance to regulatory requirements.
- The edge castellations are designed and made for prototyping, i.e. hand soldering purposes, only.
- The applicable country regulations and specific environmental regulations must be observed.
- Do not disassemble the component. Evidence of tampering will void the warranty.
- The temperature rise of the component must be taken into consideration. The operating temperature is comprised of ambient temperature and temperature rise of the component. The operating temperature of the component shall not exceed the maximum temperature specified.
- Direct mechanical impact to the component must be prevented as the material of the body, pins or terminations could flake or, in the worst case, could break. As these devices are sensitive to electrostatic discharge, proper ICHandling Procedures must be followed. These cautions and warnings comply with the state of the scientific and technical knowledge and are believed to be accurate and reliable. However, no responsibility is assumed for inaccuracies or incompleteness.

171020302

## Magl<sup>3</sup>C Power Module

### VDRM – Variable Step Down Regulator Module



#### IMPORTANT NOTES

##### General Customer Responsibility

Some goods within the product range of Würth Elektronik eiSos GmbH & Co. KG contain statements regarding general suitability for certain application areas. These statements about suitability are based on our knowledge and experience of typical requirements concerning the areas, serve as general guidance and cannot be estimated as binding statements about the suitability for a customer application. The responsibility for the applicability and use in a particular customer design is always solely within the authority of the customer. Due to this fact it is up to the customer to evaluate, where appropriate to investigate and decide whether the device with the specific product characteristics described in the product specification is valid and suitable for the respective customer application or not. Accordingly, the customer is cautioned to verify that the datasheet is current before placing orders.

##### Customer Responsibility Related to Specific, in Particular Safety-Relevant, Applications

It has to be clearly pointed out that the possibility of a malfunction of electronic components or failure before the end of the usual lifetime cannot be completely eliminated in the current state of the art, even if the products are operated within the range of the specifications. In certain customer applications requiring a very high level of safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health it must be ensured by most advanced technological aid of suitable design of the customer application that no injury or damage is caused to third parties in the event of malfunction or failure of an electronic component.

##### Best Care and Attention

Any product-specific notes, warnings and cautions must be strictly observed. Any disregard will result in the loss of warranty.

##### Customer Support for Product Specifications

Some products within the product range may contain substances which are subject to restrictions in certain jurisdictions in order to serve specific technical requirements. Necessary information is available on request. In this case the field sales engineer or the internal sales person in charge should be contacted who will be happy to support in this matter.

##### Product R&D

Due to constant product improvement product specifications may change from time to time. As a standard reporting procedure of the Product Change Notification (PCN) according to the JEDEC-Standard we inform about minor and major changes. In case of further queries regarding the PCN, the field sales engineer or the internal sales person in charge should be contacted. The basic responsibility of the customer as per Section 1 and 2 remains unaffected.

##### Product Life Cycle

Due to technical progress and economical evaluation we also reserve the right to discontinue production and delivery of products. As a standard reporting procedure of the Product Termination Notification (PTN) according to the JEDEC-Standard we will inform at an early stage about inevitable product discontinuance. According to this we cannot guarantee that all products within our product range will always be available. Therefore it needs to be verified with the field sales engineer or the internal sales person in charge about the current product availability expectancy before or when the product for application design-in disposal is considered. The approach named above does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.

##### Property Rights

All the rights for contractual products produced by Würth Elektronik eiSos GmbH & Co. KG on the basis of ideas, development contracts as well as models or templates that are subject to copyright, patent or commercial protection supplied to the customer will remain with Würth Elektronik eiSos GmbH & Co. KG. Würth Elektronik eiSos GmbH & Co. KG does not warrant or represent that any license, either expressed or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, application, or process in which Würth Elektronik eiSos GmbH & Co. KG components or services are used.

##### General Terms and Conditions

Unless otherwise agreed in individual contracts, all orders are subject to the current version of the "General Terms and Conditions of Würth Elektronik eiSos Group", last version available at [www.we-online.com](http://www.we-online.com).